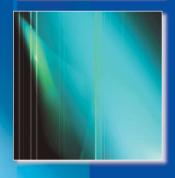


# **CNOS** LSIS

Product Catalog 2021















# SEIKO EPSON CORPORATION

# **Business Concept**

Expanding use of smartphones and tablets is giving broadband internet and wireless communications even greater roles in our daily lives, and making the arrival of the ubiquitous network society an inevitable reality. In particular, semiconductors for use in portable devices, information terminals, in-vehicle devices and FA devices are expected to provide higher performance in terms of thinner structure, lighter weight, and longer operation with limited power supply. We have been focusing on the creation of compact, low-power semiconductors since we started the development of CMOS LSI for watches in 1969. Since then, we have steadily built up our expertise in energy-saving, space-saving, and time-saving designs. This has enabled us to quickly obtain the semiconductor development technology needed to meet the demands of the new era of ubiquitous networks. Our concept is to develop "saving technologies" to reduce power consumption, development times, and implementation space. Our goal is to be a true partner for you, providing you with strategic advantages, enhancing your customer value based on our "saving technologies" and mixed analog/digital technologies that we have cultivated, as well as our design capabilities, manufacturing capabilities and stable supply that can satisfy your detailed requirements.

# **Environmental Responsibility**

Epson semiconductor technology provides environmental value to customers by creating and manufacturing eco-friendly products.

1) We Epson's products are surely complying with the Eu-RoHS (2011/65/EU) Directive.

2) We are releasing information about the containing chemical substances of products at web-site.

Product of QFP & BGA are described in the following URL.

global.epson.com/products and drivers/semicon/information/package lineup.html \*Some products are excluded.

Type of certification: ISO 14001: 2015, JIS Q 14001: 2015

Awarded to: TOHOKU EPSON CORPORATION, SEIKO EPSON CORPORATION(Fujimi Plant, Suwa Minami Plant) Certified by: Bureau Veritas Japan Co., Ltd. Date of certification: April 3, 1999

Type of certification: ISO 14001: 2015 Awarded to: Singapore Epson Industrial Pte. Ltd. Certified by: SGS Date of certification: Jan 12, 1999





# **Epson's Quality Policy**

Keeping the customer in mind at all times, we make the quality of our products and services our highest priority. From the quality-assurance efforts of each employee to the quality of our company as a whole, we devote ourselves to creating products and services that please our customers and earn their trust.

Epson has acquired ISO9001 and IATF16949 certification with its IC, module and their application products.

### ISO9001:

Type of Certification: ISO9001: 2015 , JIS Q 9001: 2015 Awarded to: TOHOKU EPSON CORPORATION, SEIKO EPSON CORPORATION(Fujimi Plant, Suwa Minami Plant, Tokyo Office) Certified by: Bureau Veritas Japan Co., Ltd. Certificate No.: 3762381 Initial Date of Certification: October 10, 1993

Type of Certification: ISO9001: 2015 Awarded to: Singapore Epson Industrial Pte. Ltd. Certified by: SGS Certificate No.: SG03/00011 Initial Date of Certification: February 4, 2003

IATF16949 Type of Certification: IATF16949: 2016 Awarded to: TOHOKU EPSON CORPORATION, SEIKO EPSON CORPORATION(Fujimi Plant, Suwa Minami Plant, Tokyo Office) Epson Europe Electronics GmbH, Epson America Inc., Epson Canada Ltd. (Vancouver Design Center)

Certified by: Bureau Veritas Certification Holding Certificate No.: 281371 Initial Date of Certification: Dec 9, 2017

Type of Certification: IATF16949: 2016 Awarded to: Singapore Epson Industrial Pte. Ltd. Certified by: SGS Certificate No.: SG07/00021 Initial Date of Certification: May 2, 2018



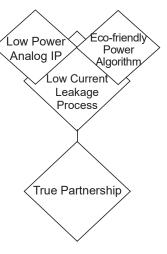




# **Epson's LSI**

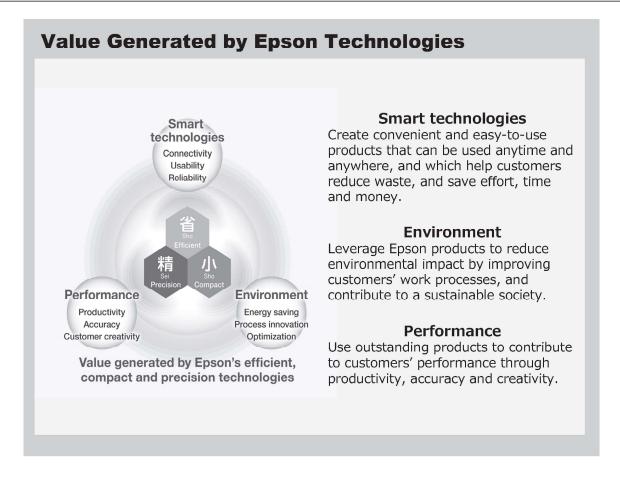
With our three core technologies - low current leakage process technology that dramatically reduces standby current, system algorithms for highly efficient power utilization, and analog IPs optimally designed for low power consumption - Epson presents solutions for you to develop applications that exceed your expectations.

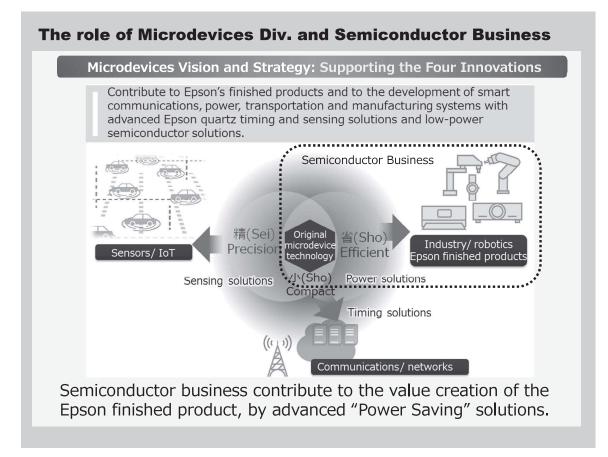
We offer optimally-designed products, information and services in a most timely manner from the very beginning of your product development to volume production. We believe our support throughout all stages of your product cycle will lead to the adoption of Epson devices for your next products.



# CMOS LSIs Contents 2021

Histor	y of Epson Semiconductor		4
		•	
_	S Application Specific IC		
		0000 series, S1L50000 series, S1L5V000 series	
	-	0000 series, S1X60000 series, S1X50000 series,	
	•	V000 series	
1-3	Standard Cells	0000 series, S1K60000 series	11
2. MCl	JS Microcontrollers		
2-1	16-bit Microcontrollers	S1C17Family	14
2-2	Arm <sup>®</sup> Cortex <sup>®</sup> -M0+ 32-bit Microcont	rollers S1C31Family	
3. ASS	PS Application Specific Standard P	roducts	
3-1	Display controllers	S1D13*** series, S2D13*** series	20
	LCD controller		
	Simple LCD controller		
	LCD controller with Camera I/F		
	Memory Display Controller		
	LCD controller for automotive		
	In-vehicle multi-camera interface	IC	
3-2	Speech & Audio		23
3-3	Thermal-head Drivers		24
3-4	EPD Drivers	S1D14F00 series	25
		s S2R72A** series, S1F773** series	25
4. REA	L TIME CLOCK MODUL		
			28
	kage Information		
5-1	Introduction of Typical Package with	High-Density Assembly	32
5-2	Package Lineup		34
	0		
LSI De	vice Precautions		39
Information	on on CMOS LSI's		44



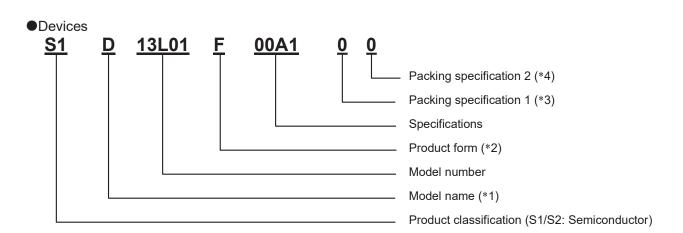


# History of Epson semiconductor

### **History of Epson Semiconductor's Technology** As the semiconductor division of "worldwide watch maker Seiko", semiconductor business has expanded into LCD Drivers, ASICs and MCUs from IC for Watches. These businesses are all based on Epson's energy-saving technology. -0-0 Automotive THE REAL LCD Driver Factory Office LCD Modul Automation Automation LCD Controller -Mobile Phone Portable 6 ASSP eBook Oscillator -Microcontroller 40 Controller Thern HealthCare 0. Head ASIC (G/A, E/A, S/C) -- World first CMOS IC for digital watches with LCD display. (1973) Scanner Custom IC (Analog) - Low voltage operation CMOS IC for analog watches that consume less than Logio Power 200nA. (1980) Supply Silicon Foundry Energy-Saving Technology ; Technology that reduces power consumption from both sides of process and circuit have been nurtured by Epson over 40 years since division was founded.

Epson Semiconduct	or	's Hi	story
富士見事業所		1969	Development of CMOS IC for watches started
	$\bigcirc$	1973	CMOS IC production started in Headquarter
	•	1980	Fujimi plant (B-wing, 4 inch) operation started
	$\bigcirc$	1984	A-wing (5 inch) operation started
	$\bigcirc$	1985	D-wing (6 inch) operation started
ARRIDE			
		1991	Sakata plant (S-wing,6 inch) operation started
	$\bullet$	1993	ISO9000 series certified
	$\bullet$	1994	Singapore assembly plant (SEP) operation started
	•	1997	T-wing (8 inch, Sakata) operation started
			ISO14001 certified
	$\bigcirc$	2001	T-wing manufacturing line expanded
	$\bigcirc$	2006	ISO/TS16949 certified
P. P. MITCH. W	٠	2010	Microdevices Operations Division started
Automated Wafer Process	$\bigcirc$	2017	IATF16949 certified

# Configuration of product number



### \*1: Model name

3rd	Model name
С	Microcontroller
D	Driver IC, Display Controller
F	USB bus switch IC
K	Standard Cell
L	Gate Array

### \*2: Product form

9th	F	Product form
В	BGA,WCSP	
D	Bare Chip	

\*3: Packing specification 1

14th	Packing specification
0	Tape & reel (non-heatproof)

### \*4: Packing specification 2

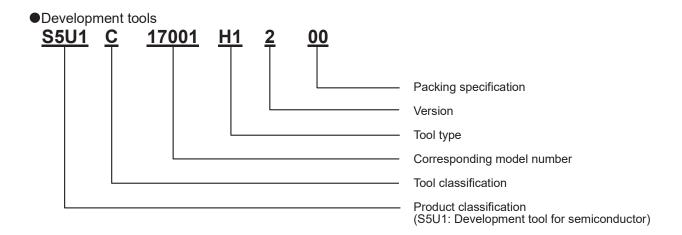
15th	Packing specifications
0	Tray
В	Tape & reel (BACK)
F	Tape & reel (FRONT)

3rd	Model name
R	USB Controller
S	Camera Interface IC
V	Speech & Audio IC
Х	Embedded Array

9th		Product form
F	QFP, QFN	
М	SOP	

14th	Packing specification
1	Tape & reel (heatproof)

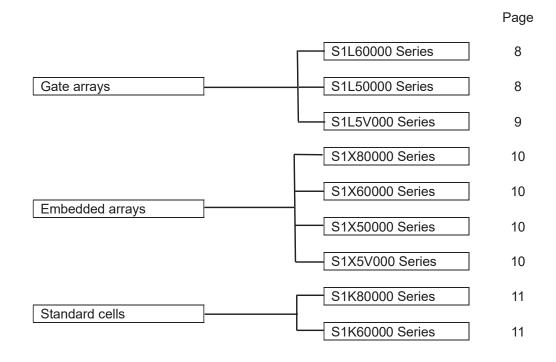
15th	Packing specifications
L	Tape & reel (LEFT)
R	Tape & reel (RIGHT)



When place an order please ask the detail product number to Epson sales representative.



# **ASICs**



Core

2.0V

I/O

# 1-1 Gate Arrays

Epson's Gate Array is a suitable solution for replacing existing devices because this Gate Array option gives flexibility to adapt the power supply and layouts of other various signals. Furthermore Epson has invested on the new Gate Array series called "S1L5V000" which supports 5V single power supply with 0.35µm process. Since it is a new series, it is also suitable for long life time applications.

											Core	I/O		
											1.8V	1.8V		
S1L60000	series										1.01	3.3V		
Ser	ries	S1L60000 \$	2.0V		2.0V 3.3V									
		• 0.25µm CMC	S, using 3-, 4-la			0.51/	2.5V							
			al gate delay at								2.5V —	3.3V		
Feat	ures				.18µW/MHz/BC				-					
					3.3V, lo∟=0.1, 1, 3									
			lo⊥=0.05, 0.3, 1, 2, 3, 6mA at 2.0V, lo⊥=0.045, 0.27, 0.9, 1.8, 2.7, 5.4mA at 1.8V) ■ RAM (synchronous type, asynchronous type), PLL, and various types of macro cells can be implemented.											
Model	3-layer Metallization	S1L60093	S1L60173	S1L60283	S1L60403	S1L60593	S1L60833	S1L61233	S1L61	583	S1L61903	S1L62513		
Name	4-layer Metallization	S1L60094	S1L60174	S1L60284	S1L60404	S1L60594	S1L60834	S1L61234	S1L61	584 S1L61904		S1L62514		
Total BC (Raw Gates)		99.2k	171.8k	284.4k	400.3k	595.4k	831.6k	1,234.9k	1,587	.8k	1,903.0k	2,519.6k		
Usable Gates	3-layer Metallization	59.6k	103.1k	142.2k	200.2k	297.7k	332.7k	494.0k	635.1	1k 761.2k		1,007.9k		
USADIe Gales	4-layer Metallization	69.5k	120.2k	184.9k	260.2k	387.0k	415.8k	617.5k	793.9	9k	951.5k	1,259.8k		
Total Lead Count Micro	80µm	_	—	—	_	—	284	344	388	38 424		488		
Lead Pitch	70µm	112	148	188	224	272	—	_	_		_	_		
	Internal Gates		tpd=107ps (2.5V operation, F/O=1, typical wiring load)											
Delay Time	Input Buffer				tpd=270ps	(2.5V operation	, F/O=2, typical v	viring load)						
Output Buffer			tpd=1600ps (2.5V operation, CL=15pF)											
I/O Le	evels		CMOS, LVTTL, PCI-3.3V											
Input Modes					LVTTL, CMOS	6, Pull-up/Pull-de	own, Schmitt, Fa	il safe, Gated						
Output	Modes				Normal, Oper	n-drain, 3-state,	Bidirectional, Fa	il safe, Gated						

# S1L50000 series

31230000	361163															
Ser	ies	S1L500	00 Serie	s									2.5V		2.5V 3.3V	
Feat	ures	<ul> <li>0.14 ns i</li> <li>Low pow</li> <li>Drive ca</li> </ul>	0.35µm CMOS, using 2-, 3- or 4-layer interconnect process     0.14 ns internal gate delay at 3.3V, 2-input power NAND Typ.     Low power consumption (Internal cell: 3.3V 0.7µW/MHz/BC)     Drive capacity (IoL=0.1, 1, 3, 8, 12, 24mA at 5.0V, IoL=0.1, 1, 2, 6, 12mA at 3.3V, IoL=0.1, 0.5, 1, 3, 6mA at 2.5V, IoL=0.05, 0.3, 0.6, 2, 4mA at 2.0V)     RAM (asynchronous type), PLL, and various types of macro cells can be implemented.													
	2-layer Metallization		ĺ							S1L52502	S1L53352	S1L54422	S1L55062	S1L56682	S1L58152	
Model Name	3-layer Metallization	S1L50063	S1L50123	S1L50283	S1L50553	S1L50753	S1L50993	S1L51253	S1L51773	S1L52503	S1L53353	S1L54423	S1L55063	S1L56683	S1L58153	
	4-layer Metallization	S1L50064	S1L50124	S1L50284	S1L50554	S1L50754	S1L50994	S1L51254	S1L51774	S1L52504	S1L53354	S1L54424	S1L55064	S1L56684	S1L58154	
Total BC (R	law Gates)	5.8k	12.0k	28.8k	55.5k	75.8k	99.2k	125.8k	177.1k	250.2k	335.9k	442.2k	506.7k	668.6k	815.5k	
	2-layer Metallization	2.9k	6.0k	14.4k	26.1k	35.7k	46.7k	56.6k	79.7k	112.6k	144.5k	176.9k	202.7k	267.5k	326.2k	
Usable Gates	3-layer Metallization	5.1k	10.6k	25.3k	47.2k	64.4k	84.4k	100.7k	132.8k	187.7k	251.9k	309.5k	354.7k	468.0k	570.9k	
	4-layer Metallization	5.5k	11.4k	27.3k	52.8k	72.0k	94.3k	119.5k	168.2k	237.7k	319.1k	397.9k	456.1k	601.7k	734.0k	
Total Lead Count Micro	80µm	-	56	88	124	144	168	188	224	264	308	352	376	432	480	
Lead Pitch	70µm	48	64	104	144	168	192	216	-	-	—	-	-	-	-	
	Internal Gates			tpd=0.1	4ns (3.3V c	peration, F	/O=2, typica	al wiring loa	d), 0.21ns (	2.0V operat	ion, F/O=2,	typical wiri	ng load)			
Delay Time	Input Buffer	tpd=0.	38ns (5.0V o	operation, F/	/O=2, typica	l wiring load	), 0.4ns (3.3	V operation	, F/O=2, typ	ical wiring lo	oad), 1.3ns (	2.0V operat	tion, F/O=2,	typical wirin	ig load)	
	Output Buffer			tpd=2	.12ns (5.0V	operation, C	C∟=15pF), 2.	02ns (3.3V	operation, C	∟=15pF), 3.9	9ns (2.0V op	eration, C⊦	=15pF)			
I/O Le	evels						СМО	S, LVTTL, F	PCI-5V, PCI	-3.3V						
Input N	Nodes					LVTTL	, CMOS, Pu	III-up/Pull-d	own, Schmi	tt, Fail safe	Gated					
Output	Modes					Norma	al, Open-dra	iin, 3-state,	Bidirectiona	al, Fail safe,	Gated					
							.,	, •,		.,,						

Note: Figures shown for usable gates are approximations. The actual number of usable gates varies according to the implemented circuitry.

S1L5V000	Series							Core	I/O
								5.0V	5.0V
Sei	ies	S1L5V000 Sei	ries					3.3V	3.3V
Feat	ures	<ul> <li>Internal gate dela</li> <li>Low power consi</li> </ul>	ay: 0.19 ns at 5 V, 0. umption (Internal ce ⊳∟=0.1, 1, 3, 8, 12m/	terconnect process .29 ns/ at 3.3V, 2-inp II: 5V 1.3μW/MHz/B0 A at 5.0V, Io∟=0.1, 1, plemented	C, 3.3V 0.54µW/MH	z/BC)	S1L5V252         -           S1L5V253         S1X5V5           S1L5V254         S1X5V5           254.3k         235.0           63.5k         -           139.8k         129.3           165.3k         152.6           256         pperation, F/O=2, typical wiring load           pperation, F/O=2, typical wiring load		
	2-layer Metallization	S1L5V012	S1L5V042	_	S1L5V112	_	S1L5V252	-	S1L5V482
Model Name	3-layer Metallization	S1L5V013	S1L5V043	S1X5V513*	S1L5V113	S1X5V523*	S1L5V253	S1X5V533*	S1L5V483
	4-layer Metallization	S1L5V014	S1L5V044	S1X5V514*	S1L5V114	S1X5V524*	S1L5V254	S1X5V534×	S1L5V484
Total BC (F	Raw Gates)	8.8k	42.0k	26.0k	109.2k	90.3k	254.3k	235.0k	479.9k
	2-layer Metallization	2.6k	12.6k	_	32.7k	-	63.5k	-	119.9k
Jsable Gates	3-layer Metallization	5.3k	25.2k	14.3k	65.5k	49.7k	139.8k	129.3k	239.9k
	4-layer Metallization	6.1k	29.4k	16.9k	76.4k	58.7k	165.3k	152.8k	287.9k
Total Lea	ad Count	48	1	04	1	68	2	56	308
	Internal Gates		tpd=0.19ns	(5.0V operation, F/O	=2, typical wiring loa	ad), 0.29ns(3.3V ope	ration, F/O=2, typic	al wiring load)	
Delay Time	Input Buffer		tpd=0.45ns	(5.0V operation, F/O	=2, typical wiring loa	ad), 0.55ns(3.3V ope	ration, F/O=2, typic	al wiring load)	
	Output Buffer			tpd=2.07ns (5.0	V operation, C∟=15p	F), 2.95ns (3.3V ope	ration, C∟=15pF)		
I/O L	evels				CMOS, T	TL, LVTTL			
Input I						ll-down, Schmitt, Fail			
Output	Modes			Normal, (	Open-drain, 3-state,	Bidirectional, Fail-sa	fe, Gated		

\*: Analog PLL built in master.

Note: Figures shown for usable gates are approximations. The actual number of usable gates varies according to the implemented circuitry.

ASICs

# 1-2 Embedded Arrays

An embedded array is an ASIC under a new method featuring consolidation of "Sea of gates" of a gate array and hard- macros installed in standard cells for specific applications. With this product, the concept of system-on-chip has been realized by consolidation of hard-macro cells for specific applications and a shorter gate array development period has become available, thanks to adoption of the "Sea of Gates" for the logic portion.

# Designing the embedded arrays

When designing embedded arrays, execute system design first and determine the number of gates for the logic section and select the macro-cell to be used before starting manufacture of base bulks. The base bulks, placing necessary hard-macro cells and the Sea of Gates for the logic portion, are manufactured up to just before the routing process. In parallel with this manufacturing processes, processes from the circuit designing of the logic portion through post-simulation fix should be executed, similar to the cases of ordinary gate arrays, to go into sample production process after sign-off.

After the sign-off, samples can be shipped with the same delivery leadtime as that of the gate arrays. Also, when making logic circuit modifications or ROM data changes, developing cost and leadtime can be reduced to a level similar to that of the gate arrays.

# Embedded arrays lineup

		Core	I/O
S1X80000	series	1.8V	3.3∨
Series	S1X80000 Series	LDO	3.3V
Features	Based on 0.15µm CMOS process technology using 4/5-layer interconnect process     Internal gate delay: 47.1ps/1.8V, 2-input NAND Typ.     Lower power consumption (Internal cell: 0.063µW //MHz/gate 2-input NAND Typ.)     Drive performance (lo=2,4,8,12mA at 3.3V)		
Macro Cells	RAM, ROM, LVDS, RSDS, various types of macro cells		
Package	48 to 256 pin QFP, PBGA, PFBGA, SQFN		

		Core	I/O
S1X60000	series	2.0V	2.0V
Series	S1X60000 Series	2.5V	3.3V 2.5V
Features	<ul> <li>Based on 0.25µm CMOS process technology and 3/4/5-layer wiring technology, number of raw gates: 2,500,000 Max.</li> <li>Internal gate delay: 107ps/2.5V, 2-input NAND Typ.</li> <li>Low power consumption (Internal cell: 0.18µW/MHz/gate, 2.5V, Typ.)</li> <li>Drive performance (loc=0.1, 1, 3, 6, 12, 24mA at 3.3V, loc=0.1, 1, 3, 6, 12, 24mA at 2.5V, loc=0.05, 0.3, 1, 2, 4, 8mA at 2.0V)</li> </ul>	L	3.3V
Macro Cells	RAM, ROM, various types of macro cells		
Package	48 to 256 pin QFP, PBGA, PFBGA, SQFN		
		Core	I/O

### S1X50000 series

21720000	series		0.01
		2.5V	2.5V
Series	S1X50000 Series	2.01	3.3V
1	<ul> <li>Based on 0.35µm CMOS process technology and 3/4-layer wiring technology</li> </ul>	3.3V	3.3V
	Internal gate delay: 150ps/3.3V, 2-input power NAND Typ.	0.01	5.0V
Features	Low power consumption (Internal cell: 0.37µW/MHz/gate, 3.3V, Typ.)		
	● Drive performance (IoL=0.1, 1, 3, 8, 12, 24mA at 5.0V, IoL=0.1, 1, 2, 6, 12mA at 3.3V, IoL=0.1, 0.5, 1, 3, 6mA at 2.5V, IoL=0.05, 0.3, 0.6	i, 2, 4mA at 2.0V)	
Macro Cells	RAM, ROM, various types of macro cells		
Package	48 to 256 pin QFP, PBGA, PFBGA, SQFN		

		Core	I/O
S1X5V000	series	3.3V	3.3V
Series	S1X5V000 Series	5.0V	5.0V
	<ul> <li>Based on 0.35µm CMOS process technology and 2/3/4-layer wiring technology</li> <li>Internal gate delay: 190ps/5.0V, 290ps/3.3V, 2-input power NAND Typ.</li> <li>Low power consumption (Internal cell: 1.3µW/MHz/gate, 5.0V, 0.54µW/MHz/gate, 3.3V, Typ.)</li> <li>Drive performance (loL =0.1, 1, 3, 8, 12mA at 5.0V, loL =0.1, 1, 2, 6, 10mA at 3.3V)</li> </ul>	L	
Macro Cells	RAM, PLL		
Package	48 to 256 pin QFP, PBGA, PFBGA, SQFN		

2.0V

2.0V

# 1-3 Standard Cells

# Standard Cells

The standard cells are semi-custom ICs that incorporates a well-designed internal logic cell and RAM/ROM, CPU peripheral circuits or analog circuits into a single chip. Compared to the gate arrays, they boast higher design flexibility, functionality and integration capabilities, providing system LSI chips optimized to the customer needs. These features greatly help electronic device manufacturers design products with a compact body, lower power consumption, and a lower cost.

		Core	1/0
S1K80000	series	1.8V	3.3V
Series	S1K80000 Series	LDO	3.3V
Features	Based on 0.15um CMOS process technology using 4/5-layer interconnect process     Internal gate delay: 43.9ps/1.8V, 2-input NAND Typ.     Lower power consumption (Internal cell: 0.03µ,W /MHz/gate 2-input NAND Typ.)     Drive performance (lo.=2,4,8,12mA at 3.3V)	1	
Macro Cells	RAM, ROM, LVDS, RSDS, various types of macro cells		
Packages	48 to 256 pin QFP, PBGA, PFBGA, SQFN		

		Core	I/O
S1K60000	series	2.0V	2.0V
Series	S1K60000 Series	2.5V	3.3V 2.5V
Features	<ul> <li>0.25µm CMOS, using 3-, 4- or 5-layer interconnect process, number of raw gates: 3,900,000 Max.</li> <li>Internal gate delay:106ps/2.5V, 2-input NAND Typ.</li> <li>Low power consumption (Internal cell: 0.09µW/MHz/gate, 2.5V, Typ.)</li> <li>Drive capacity (lou=0.1, 1, 3, 6, 12mA at 3.3V, lou=0.1, 1, 3, 6, 9, 18mA at 2.5V, lou=0.05, 0.3, 1, 2, 3, 6mA at 2.0V)</li> </ul>		3.3V
Macro Cells	RAM, ROM, various types of macro cells		
Packages	48 pin to 256 pin QFP, PBGA, PFBGA, SQFN		

# 1-4 Development of ASICs

ASICs are developed you to coraborate with Epson. We are preparing design libraries for various ASIC development tools

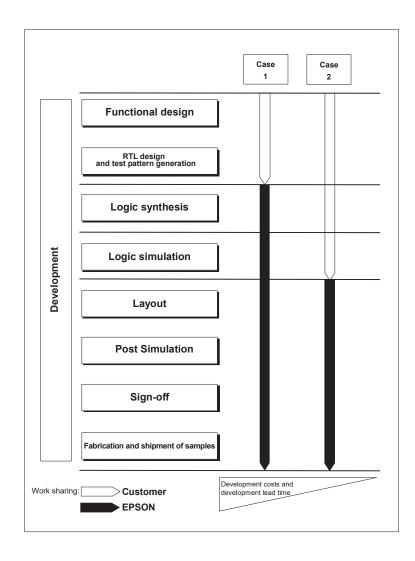
### Case1. RTL Interface

After taking development as far as the function simulation stage, customers can send their Verilog-HDL or VHDL source files and test patterns to Epson via an HDL interface, so that Epson can perform logic synthesis.

### Case2. Pre-Sim Interface

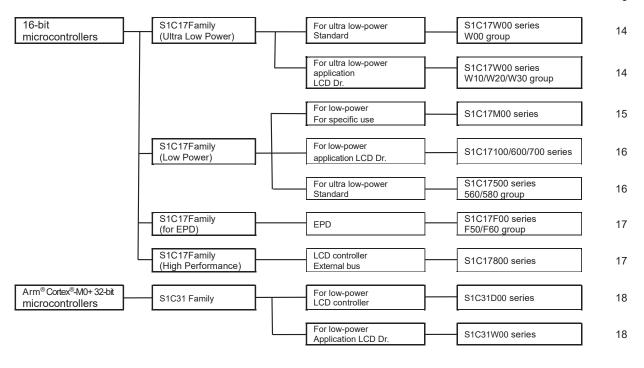
Customers can use this interface to send Epson gate-level netlists and test patterns for Verilog-HDL or VHDL code that has completed the logic simulation stage.

Epson will then perform the subsequent tasks beginning with interconnect layout.



2

# MCUs



Page

### 16-bit Microcontrollers 2-1

The S1C17 Family, 16-bit RISC microcontrollers integrate a wide variety of peripheral circuits such 16-bit RISC as various interfaces that meet various types of sensors and the EPD Driver/controller, LCD Microcontrollers driver/controller that covers the wide display area into a single chip design. They can realize both S1C17 Family high-speed operation and low power consumption, and provide the products suitable to portable Application-oriented gears. Also, various flash ROM built-in products are lined up. The flexible development environment microcontroller and on-chip ICE functions can shorten the product development period.

### S1C17W00 series W00 group (Ultra Low Power)

This is an ultra-low power consumption 16-bit MCU compatible to low voltage operations from 1.2V, even with built-in flash memory. The embedded highly efficient DC-DC converter generates an internal constant voltage, to drive an IC with a low power consumption operation beyond Seiko Epson's 4-bit MCUs.

This product is equipped with a built-in RTC, stopwatch, high-performance PWM, external bus I/F and improved analog functions, combined with the powerful processing capacity of the 16-bit CPU, suitable for battery driven applications.

	Display	(	Operation of	lock	Supply current		Mem	ory	I/O		Ti	mer				SIO				+	t.			
Products	LCD Driver segxcom	High speed [Hz] (Max.)	Low speed [Hz] (Typ.)	Built-in oscillator [Hz] (Typ.)	Sleep/ Halt/ operating(32K)/ operating(1M) [µA] (Typ.)	Supply voltage [V]	Flash ROM [Byte]	RAM [Byte]	I/O port %6	16-bit	16-bit PWM	WDT	Clock Real Time Clock	UART	IdS	I <sup>2</sup> C master	I <sup>2</sup> C slave	Remote control circuit	Sound generator	R/F converter, 24-bit	A/D converter, 12-bit	Multiplier/Divider	SVD %3	Package (Form of delivery)
S1C17W03	—	4.2M	32.768k	250k/384k/ 500k/700k/ 1M/2M/4M	0.15/0.3/ 4/250	1.2 to 3.6 ※1	16K ※2	2K	35 24	4	2x2	1 -	_ 1 **	2	2	1	1	1	1	2 ※4 1	6 5	1	1	Chip TQFP12-48 SQFN5-32
S1C17W04	—	4.2M	32.768k	250k/384k/ 500k/700k/ 1M/2M/4M	0.15/0.3/ 4/250	1.2 to 3.6 ※1	32K ※2	2K	35 24	4	2x2	1 -	_ 1 **	2	2	1	1	1	1	2 ※4	6 5	1	1	Chip TQFP12-48 SQFN5-32

\*1: During erasing / programming in flash memory (V₀₀): 1.8 to 3.6%
 \*2: During erasing / programming in voltage flash memory(V₀₀): The external applying 7.5V / 7.5V(Typ.) is needed.
 \*3: SVD is an abbreviation for Supply Voltage Detector.
 \*4: Independent operation for each channel.
 \*5: Stoymatch function.
 \*6: Including Input port and Output port.

# S1C17W00 series W10/W20/W30 group (Ultra Low Power)

This is an ultra-low power consumption 16-bit MCU compatible to low voltage operations from 1.2V, even with built-in flash memory. The embedded highly efficient DC-DC converter generates an internal constant voltage, to drive an IC with a low power consumption operation beyond Seiko Epson's 4-bit MCUs.

This product is equipped with a built-in RTC, stopwatch, LCD driver, high-performance PWM and improved analog functions, combined with the powerful processing capacity of the 16-bit CPU, suitable for battery driven applications that require a LCD and clock function.

<u> </u>			/		,									×	_	-			_	_	_	_	_	
	Display	(	Operation o	clock	Supply current		Men	nory	I/O		Tin	ner	10			SIO	I	ij	r	24-bit	12-bit	sr		
Products	LCD Driver segxcom	High speed [Hz] (Max.)	Low speed [Hz] (Typ.)	Built-in oscillator [Hz] (Typ.)	Sleep/ Halt/ operating(32K)/ operating(1M) [µA] (Typ.)	Supply voltage [V]	Flash ROM [Byte]	RAM [Byte]	I/O port ※9	16-bit	16-bit PWM	WDT	Real Time Clock 35	UART	SPI	QSPI	I <sup>2</sup> C	Remote control circuit	Sound generator	R/F converter, 24	A/D converter, 12	Multiplier/Divider	SVD %7	Other functions, Package (Form of delivery)
	26 x 4		32.768k	32k/250k/ 384k/500k/	0.15/0.3/ 2/140	1.2 to 3.6	48K		32															LED pin x 2 Chip
S1C17W12	18 x 4	4.2M	_	700k/ 1M/2M/4M	0.15/1.5/ 5/140	*10	×4	2K	26	3	2x2	1	1	2	1	-	1	1	1	1	-	1	1	LED pin x 2 SQFN7-48
S1C17W13	26 x 4	4.2M	32.768k	32k/250k/ 384k/500k/	0.15/0.3/ 2/140	1.2 to 3.6	48K	2K	32	3	2x2	1	1	2	1		1	1	1	1		1	1	LED pin x 2 Chip QFP13-64
310171013	18 x 4 20 x 4 ※8	4.211	32.700K	700k/ 1M/2M/4M	0.15/0.3/ 4/140	<b>※10</b>	₩4	21	26	3	202	1	1	2	'		1	'	'	_	_	1	1	SQFN7-48 TQFP12-48
S1C17W14	54 x 4 50 x 8	4.2M	32.768k	250k/384k/ 500k/700k/ 1M/2M/4M	0.15/0.3/ 3/200	1.2 to 3.6 ※1	48K ※4	4K	33	3	252	1	1	2	2	-	1	1	1	1	Ι	1	1	Chip QFP15-100
	34 x 4 30 x 8				0.15/0.3/				36															Chip QFP15-100
S1C17W15	32 x 4 28 x 8	4.2M	32.768k	500k/700k/ 1M/2M/4M	4/250	1.2 to 3.6 ※1	64K ※4	4K	33	3	2x2	1	1	2	1	-	1	_	1	4 ※6	-	1	1	TQFP14-80
	24 x 4 20 x 8				0.15/0.5/ 8/250				28															SQFN9-64 TQFP13-64
S1C17W16	60 x 4 56 x 8	4.2M	32.768k	250k/384k/ 500k/700k/ 1M/2M/4M	0.15/0.3/ 3/200	1.2 to 3.6 ※1	64K ⊛4	8K	40	5	2x2	1	1	2	3	-	1	1	1	2 ※6	4	1	1	Chip TQFP15-128
	48 x 4 44 x 8			250k/384k/	0.15/0.3/ 2/140	1.2 to 3.6	128K		68											2				Temperature sensor, Chip TQFP15-128
S1C17W18	32 x 4 28 x 8	4.2M	32.768k	500k/700k/ 1M/2M/4M	0.15/0.5/	*2 *2	(※4)	8K	57	4	3x2	1	1	2	2	-	1	1	1	×6	7	1	1	TQFP14-80
	24 x 4 20 x 8				4/140				49															SQFN9-64
S1C17W22	72 x 4/8 64 x 16 56 x 24	4.2M	32.768k	500k/700k/ 1M/2M/4M	0.15/0.3/ 4/250	1.2 to 3.6 ※1	64K ※4	4K	42	2	2x2	1	1	1	1	-	1	1	1	2 ※6	-	1	1	Chip TQFP15-128
S1C17W23	72 x 4/8 64 x 16 56 x 24	4.2M	32.768k	500k/700k/ 1M/2M/4M	0.15/0.3/ 4/250	1.2 to 3.6 ※1	96K ※4	8K	42	4	3x2	1	1	2	2	_	1	1	1	2 ※6	6	1	1	Chip TQFP15-128
S1C17W34	80 x 16 64 x 32	4.2M	32.768k	250k/384k/ 500k/700k/ 1M/2M/4M	0.15/0.4/ 3/150	1.2 to 3.6 ※2,3	128K (※4)	12K	53	4	3x2	1	3	2	2	_	1	1	1	2 ※6	7	1	1	Temperature sensor, Chip QFP21-176
S1C17W35	80 x 16 64 x 32	4.2M	32.768k	250k/384k/ 500k/700k/ 1M/2M/4M	0.15/0.4/ 3/150	1.2 to 3.6 ※2,3	256K (※4)	12K	53	4	3x2	1	3	2	2	-	1	1	1	2 ※6	7	1	1	Temperature sensor, Chip QFP21-176
S1C17W36	80 x 16 64 x 32	4.2M	32.768k	250k/384k/ 500k/700k/ 1M/2M/4M	0.15/0.4/ 3/150	1.2 to 3.6 ※2,3	384K (※4)	16K	53	4	3x2	1	3	2	2	—	1	1	1	2 ※6	7	1	1	Temperature sensor, Chip QFP21-176

\*2: \*4: \*5: \*6: \*7: \*8: \*9: \*10:

During erasing / programming in flash memory (Voc): 1.8 to 3.8V (without the external Voc applying), 2.4 to 3.6V (during the external applying). During erasing / programming in flash memory (Voc): 2.7 to 3.6V (without the external Voc applying), 2.4 to 3.6V (during the external applying). During erasing / programming in voltage flash memory (Voc): 2.7 to 3.6V (without the external Voc applying), 2.4 to 3.6V (during the external applying). During erasing / programming in voltage flash memory (Voc): 2.7 to 3.6V (without the external Applying 7.5V / 7.5V(Typ.) is needed. Regarding to (×4), Flash memory could be erased/programmed by internal power as well. With stopwatch function. Independent operation for each channel. SVD is an abbreviation for Supply Voltage Detector. External voltage application mode only. Muring erasing / programming in flash memory (Voc): 2.4V to 3.6V

### S1C17M00 series (For specific use with Low Power)

This series is an application-specific type.

This is a 16-bit MCU with built-in flash memory, which realizes high-speed processing at low power consumption and supports the power supply voltage from 1.8V to 5.5V.

	Display	0.0 V.	peration cl	lock	Supply current		M	emor	у	I/O		Tim	ner				SIO			-	bit	bit	L		
Products	Display Driver	High speed [Hz] (Max.)	Low speed [Hz] (Typ.)	Built-in oscilator [Hz] (Typ.)	Sleep/ Halt/ Operating (32K)/ Operating (1M) [µA] (Typ.)	Supply voltage [V]	Flash ROM [Byte]	EEPROM [Byte]	RAM [Byte]	I/O port ※8	16-bit	16-bit PWM	WDT	Real Time Clock	UART	SPI	QSPI	I <sup>2</sup> C	Remote control circuit	Sound generator	R/F converter, 24-bit	A/D converter, 12-bit	Multiplier/Divider	SVD %6	Other functions, Package (Form of delivery)
S1C17M01	32 ×4 (LCD) 28 ×8 (LCD)	16.3M	32.768k	7.37M	0.35/0.8/ 12.5/210	1.8 to 5.5 %1	32K ※4	—	4K	19	5	-	1	1	1	2	—	1	_	_	1	_	_	1	AMRC, Chip TQFP13-64
S1C17M10	88×8 (LCD) 80×16 (LCD)	16.8M	32.768k	32k/ 4M/8M 12M/16M	0.16/0.6/ 4/145	1.8 to 5.5 %2	64K (※4)	_	4K	33	5	1x2	1	1	1	1	_	1	_	_	_	_	1	1	SMCIF, Chip TQFP15-128
S1C17M12	8×5 (LED)	16.8M	_	4M/8M/ 12M/16M	0.35/40/ —/150	1.8 to 5.5 %3	16K ※4	-	2K	39	4	1x2	1	_	1	2	—	1	1	—	—	_	1	1	Heavy current Port, Chip TQFP12-48
S1C17M13	8×5 (LED)	16.8M	_	4M/8M/ 12M/16M/	0.35/40/ —/150	1.8 to 5.5 %3	16K ※4	—	2K	39	4	1x2	1	_	1	2	—	1	1	_	_	8	1	1	Heavy current Port, Chip TQFP12-48
S1C17M20	_	21M	_	32k/700k/ 12M/16M/	0.36/1.5/ 5.5/160	1.8 to 5.5		_	2K	18	4	2x2	1	1	2	2		1	1	1	_	4	1	1	SQFN4-24
		2	32.768k	20M	0.36/0.7/ 5/160	*2	(※4)			24		2/12			-	-						6			SQFN5-32
S1C17M21	_	21M	32.768k	32k/700k/ 12M/16M/ 20M	0.36/0.7/ 5/160	1.8 to 5.5 %2	16K (※4)	_	2K	24	4	2x2	1	1	2	2	-	1	1	1	_	6	1	1	TQFP12-32
S1C17M22	_	21M	32.768k	32k/700k/ 12M/16M/ 20M	0.36/0.7/ 5/160	1.8 to 5.5 %2	16K (※4)	-	2K	40	4	2x2	1	1	2	2	—	1	1	1	2	8	1	1	TQFP12-48
S1C17M23	_	21M	_	32k/700k/ 12M/16M/	0.36/1.5/ 5.5/160	1.8 to 5.5		_	2K	18	4	2x2	1	1	2	2		1	1	1	_	4	1	1	SQFN4-24
			32.768k	20M	0.36/0.7/ 5/160	*2	(※4)			24												6			SQFN5-32
S1C17M24	_	21M	32.768k	32k/700k/ 12M/16M/ 20M	0.36/0.7/ 5/160	1.8 to 5.5 ※2	32K (※4)	_	2K	24	4	2x2	1	1	2	2	-	1	1	1	_	6	1	1	TQFP12-32
S1C17M25	_	21M	32.768k	32k/700k/ 12M/16M/ 20M	0.36/0.7/ 5/160	1.8 to 5.5 %2	32K (※4)	-	2K	40	4	2x2	1	1	2	2	—	1	1	1	2	8	1	1	TQFP12-48
S1C17M30	26×4 (LCD) 22×8 (LCD) ※7	16.8M	32.768k	32k/700k/ 12M/16M	0.2/0.7/ 5/160	1.8 to 5.5 %2	48K (※4)	_	4K	38	4	3x2	1	1	2	2	—	1	1	1	2	2	1	1	TQFP12-48
S1C17M31	26 ×4 (LCD) 22 ×8 (LCD)	16.8M		32k/700k/ 12M/16M	0.2/1.4/ 5.5/160	1.8 to 5.5 %2	48K (※4)	_	4K	38	4	3x2	1	1	2	2	—	1	1	1	2	2	1	1	TQFP12-48
S1C17M32	42×4 (LCD) 38×8 (LCD) ※7	16.8M	32.768k	32k/700k/ 12M/16M	0.2/0.7/ 5/160	1.8 to 5.5 ※2	64K (※4)	_	4K	54	4	3x2	1	1	2	2	_	1	1	1	2	2	1	1	TQFP13-64
S1C17M33	50 ×4 (LCD) 46 ×8 (LCD)	16.8M	32.768k	32k/700k/ 12M/16M	0.2/0.7/ 5/160	1.8 to 5.5 %2	96K (※4)	_	4K	66	4	3x2	1	1	2	2	—	1	1	1	2	5	1	1	Chip TQFP14-80
S1C17M34	37 x 4 (LCD) 33 x 8 (LCD)	16.8M	32.768k	32k/700k/ 12M/16M	0.2/0.7/ 5/160	1.8 to 5.5 ※2	64K (※4)	_	4K	52	4	3x2	1	1	2	2	—	1	1	1	2	5	1	1	TQFP13-64
S1C17M40	40×4(LCD) 36×8(LCD) 28×4(LCD)	16.8M	32.768k	32k/ 700k/ 16M	0.25/0.7/ 5/— 0.25/1.4/	1.8 to 5.5 ※9,10	48K (※4)	256	2K	55 41	4	3×2	1	1	3	2	_	1	1	1	_	4	1	1	QFP13-64pin TQFP12-48pin

%1: AMRC (MR sensor controller) Operation (VDD): 2.0V to 5.5V

\*: I: ANIKC (MR sensor controller) Operation (Vob): 2.0V to 5.5V
\*: ANIKC (MR sensor controller) Operation (Vob): 2.0V to 5.5V
\*: During erasing / programming in flash memory (Vob): 2.7V to 5.5V (without the external VPP applying), 2.4V to 5.5V (during the external VPP applying).
\*: During erasing / programming in flash memory (Vob): 2.4V to 5.5V
\*: During erasing / programming in flash memory (Vob): 2.4V to 5.5V
\*: During erasing / programming voltage in flash memory (Vob): 2.4V to 5.5V
\*: During erasing / programming voltage in flash memory (VPP): The external applying of 7.5V / 7.5V(Typ.) is needed. Regarding to (\*4), Flash memory could be erased/programmed by internal power as well.
\*: S: With stopwatch function.
\*: SVD is an abbreviation for Supply Voltage Detector.(power supply voltage detector circuit)
\*: External voltage application mode only.

%8: Including Input port and Output port.

S1C17100/600/700 series (Low Power) This 16-bit MCU has improved the throughput and the development environment while maintaining low power consumption just like 4/8-bit Epson MCU. This 16-bit MCU incorporates an LCD driver, power circuit, clock function and various types of I/F. It enables to realize applications with 1 chip. This MCU is the most suitable for portable terminals such as clock, watch and remote controller.

	Display	C	peration of	clock	Supply current		1	Memory	/	I/O			1	Fimer						SIO				t	t			
Products	LCD Driver segxcom	High speed [Hz] (Max.)	Low speed [Hz] (Typ.)	Built-in oscillator [Hz] (Typ.)	Sleep/ Halt/ operating(32K)/ operating(1M) [µA] (Typ.)	Supply voltage [V]	Flash ROM [Byte]	Mask ROM [Byte]	RAM [Byte]	I/O port %8	8-bit	16-bit	16-bit PWM	Stopwatch	WDT	Clock	Real Time Clock	UART	SPI	I <sup>2</sup> C master	I <sup>2</sup> C slave	Remote control circuit	Sound generator	R/F converter, 24-bit	A/D converter, 10-bit	Multiplier/Divider	SVD %5	Package (Form of delivery)
S1C17153	32 x 4	_	32.768k	500K/1M/ 2M	0.13/0.42/4.0/ 160	2.0 to 3.6	-	16K	2K	12	1	—	1	-	1	1	1	1	1	—	-	—	1	_	—	1	1	Chip
S1C17121	40 x 4 36 x 8	4.2M	32.768k	2.7M	0.15/0.9/7.0/ 250	1.8 to 3.6	-	32K	2K	36	3	3	1	1	1	1	-	2	1	1	1	1	—	2	8	1	1	Chip TQFP14-100
S1C17651	20 x 4	4.2M	32.768k	32K/500K/ 1M/2M	0.09/0.42/10.0/ 350	2.0 to 3.6	×3	_	2K	12	1	-	1	—	1	1	1	1	1	—	Ι	—	1	Ι	—	1	1	Chip TQFP13-64
S1C17653	32 x 4	4.2M	32.768k	32K/500K/ 1M/2M	0.09/0.42/10.0/ 350	2.0 to 3.6	16K ※3	_	2K	12	1	-	1	-	1	1	1	1	1	—	—	_	1	-	_	1	1	Chip %7 TQFP14-80
S1C17656	32 x 4	-	32.768k	500K/1M/ 2M/4M	0.13/0.5/7.3/ 280	1.8 to 3.6	24K ※4	_	2K	20	1	-	1	—	1	1	1	1	1	—	Ι	—	1	1	—	1	1	Chip TQFP14-80
S1C17611	12 x 4 8 x 8	8.2M	32.768k	2.7M	0.6/2.0/12.0/ 400	1.8 to 3.6 %1	*6	-	2K	19	2	3	2	1	1	1	-	1	1	1	1	_	-	1	4	1	1	Chip QFP12-48
S1C17601	20 x 4 16 x 8	8.2M	32.768k	2.7M	0.6/2.0/12.0/ 340	1.8 to 3.6 ※1	32K ※6	-	2K	24	2	3	2	1	1	1	-	1	1	1	1	-	-	1	4	1	1	Chip TQFP13-64
S1C17621	40 x 4 36 x 8	8.2M	32.768k	2.7M	0.75/2.5/15.0/ 410	1.8 to 3.6 %1	32K ※6	_	2K	36	3	3	1	1	1	1	_	2	1	1	1	1	-	2	8	1	1	Chip TQFP14-100
S1C17602	40 x 4 36 x 8	8.2M	32.768k	2.7M	0.75/2.5/15.0/ 410	1.8 to 3.6 ※1	64K ※6	-	4K	36	3	3	1	1	1	1	-	2	1	1	1	1	-	2	8	1	1	Chip TQFP14-100
S1C17622	56 x 4 52 x 8	8.2M	32.768k	2.7M	0.75/2.3/14.0/ 400	1.8 to 3.6 %1	64K ※6	_	4K	47	3	3	1	1	1	1	-	2	1	1	1	1	-	2	8	1	1	Chip TQFP15-128
S1C17604	40 x 4 36 x 8	8.2M	32.768k	2.7M	0.75/2.3/14.0/ 400	1.8 to 3.6 ※1	128K ※6	-	8K	36	3	3	3	1	1	1	1	2	1	1	1	1	-	2	8	1	1	Chip TQFP14-100
S1C17624	56 x 4 52 x 8	8.2M	32.768k	2.7M	0.75/2.3/14.0/ 400	1.8 to 3.6 ※1	128K ※6	-	8K	47	3	3	3	1	1	1	1	2	1	1	1	1	-	2	8	1	1	Chip TQFP15-128
S1C17711	64 x 16 56 x 24	8.2M	32.768k	2.7M	1.0/2.0/12.0/ 400	1.8 to 3.6 %1	64K ※6	_	4K	29	-	4	4	1	1	1	-	1	1	1	1	1	-	2	8	1	1	Chip TQFP15-128
S1C17702	88 x 16 72 x 32	8.2M	32.768k	2.7M	1.0/2.5/16.0/ 450	1.8 to 3.6 ※1	128K ※6	-	12K	28	3	3	2	1	1	1	-	1	1	1	-	1	_	Ι	_	1	1	Chip QFP21-176 VFBGA10H-180 VFBGA8H-181
S1C17703	120 x 16/24/32 60 x 64	8.2M	32.768k	2.7M	1.0/2.5/15.0/ 450	1.8 to 3.6 ※2	256K ※6	_	12K	34	_	5	4	1	1	1	_	2	3	1	1	1	_	2	8	1	1	Chip VFBGA10H-240
S1C17705	128 x 16/24/32 64 x 64	8.2M	32.768k	2.7M	1.2/2.7/18.0/ 550	1.8 to 3.6 ※2	512K ※6	_	12K	35	_	5	4	1	1	1	—	2	3	1	1	1	_	2	8	1	1	Chip VFBGA10H-240

\*1: During erasing / programming in flash memory (VDD): 2.7 to 3.6V

x1: Juring erasing / programming in flash memory (V<sub>10</sub>): 2.7 to 3.6V
x2: During erasing / programming in holtash memory (V<sub>10</sub>): 2.5 to 3.6V
x3: During erasing / programming in voltage flash memory(V<sub>PP</sub>): The external applying 7.5V / 7.0V(Typ.) is needed.
x4: During erasing / programming in voltage flash memory(V<sub>PP</sub>): The external applying 7.5V / 7.5V(Typ.) is needed.
x5: SVD is an abbreviation for Supply Voltage Detector.(power supply voltage detector circuit)
x6: This product uses SuperFlash<sup>®</sup> technology licensed from SST UK Ltd. in U.K.
x7: Au bump is available.
x8: Including Input port and Output port.

### S1C17500 series (Low Power)

This is a 16-bit MCU with built-in flash memory, which realizes high-speed processing at low power consumption. This product is equipped with various features, such as general-purpose I/O ports, A/D converter input and serial I/F. It's suitable for controlling various sensor built-in devices and household appliances.

	Display	Op	peration clo	ock	Supply current		N	/lemoi	y	I/O			Time	r				SIC	)			÷	it			
Products	LCD Driver segxcom	High speed [Hz] (Max.)	Low speed [Hz] (Typ.)	Built-in oscillator [Hz] (Typ.)	Sleep/ Halt/ operating (32K)/ operating (1M) [µA] (Typ.)	Supply voltage [V]	Flash ROM [Bvte]	Mask ROM [Byte]	RAM [Byte]	I/O port ※5	8-bit	16-bit PWM	Stopwatch	WDT	Clock	Real Time Clock	NAKI	I <sup>2</sup> C master	I <sup>2</sup> C slave	Remote control circuit	Sound generator	R/F converter, 24-bit	A/D converter, 10-bit	Multiplier/Divider	SVD %3	Package (Form of delivery)
S1C17564	_	24M	32.768k	2 to 12M	0.8/2.7/16.0/ 450	2.0 to 5.5	128K ※1	<	16K	40	_	5 4	1	1	1	_	2 3	5 1	1	1	Ι	_	4	1	—	Chip TQFP13-64 VFBGA5H-81
S1C17589	_	16.8M	32.768k	4M/ 8M/ 12M/ 16M	0.2/0.6/9.0/ 280	1.8 to 5.5	128K ※2	< _	16K	88 68 52	_	6 4x6	6 —	1	_	1 ※4	2 2	2 1	1	1			16 11 7	1	1	Chip QFP15-100 QFP14-80 QFP13-64

×1: During erasing / programming voltage in flash memory (VPP): The external applying of 7.5V / 7.0V(Typ.) is needed.

×2: During erasing / programming voltage in flash memory (VPP): The external applying of 7.5V / 7.5V(Typ.) is needed. \*3: SVD is an abbreviation for Supply Voltage Detector.

\*4: With stopwatch function

\*5: Including Input port and Output port.

# S1C17F00 series F50/F60 group (EPD application)

# Specific to electronic paper (EPD) applications

The product also includes embedded features such as a real-time clock, theoretical regulation, a driver capable of wringing the maximum performance from segmented EPDs and a temperature sensor. As a result, the device does not simply drive the display, but also corrects temperature effects that could harm display quality making it possible to maximize the characteristics of an e-paper display with a single chip.

	Display	0	Operation	clock	Supply current		M	emor	у	I/O			Tir	ner				SIO			bit	cttion	it			
Products	EPD Driver segment (TP/BP)	High speed [Hz] (Max.)	Low speed [Hz] (Typ.)	Built-in oscilator [Hz] (Typ.)	Sleep/ RTC/ operating(32K) / operating(1M) [µA] (Typ.)	Supply voltage [V]	Flash ROM [Byte]	EEPROM [Byte]	RAM [Byte]	I/O port %4	8-bit	16-bit	16-bit PWM	Stopwatch	Clock	Real Time Clock	UART(IrDA1.0)	SPI	I <sup>2</sup> C	Sound generator	R/F converter, 24-b	Temperature detectti	A/D converter, 12-bit	Multiplier/Divider	SVD %1	Other functions, Package (Form of delivery)
S1C17F57	64 (2TP/2BP)	4.2M	32.768k	32k/500k/ 1M/2M	0.10/0.21/ 12/410	2.0 to 3.6	32K ※2	—	2K	29	2	_	2	1 1	1	1	1	1	1	1	1	1	—	1	1	Chip %3
S1C17F63	42 (1TP/1BP)	16.8M	32.768k	500k/700k/ 1M/2M/4M/ 8M/16M	0.45/0.11/ 5/305	1.8 to 5.5 ※5,6	32K (※2)	256	2K	17	_	4 2	2×2 -	- 1	_	1 ※7	1	2	1	1	_	1	7	1	1	SMCIF, Chip%3, QFP15-100

 %1: SVD is an abbreviation for Supply Voltage Detector
 %2: During erasing / programming voltage in flash memory (VPP): The external applying of 7.0V / 7.5V(Typ.) is needed. Regarding to (%2), Flash memory could be erased/programmed by internal power as well.

%3: Au bump is available.

%4: Including Input port and Output port.

%5: During erasing / programming in flash memory(VDD): 2.2V to 5.5V

%6: During programming in EEPROM(VDD): 2.2V to 5.5V

%7: With stopwatchfunction

				Memory	comm interfa		Operation clock		-		
Products	EPD Driver segment (TP/BP)	Supply voltage [V]	EPD Drive voltage [V]	Flash ROM [Byte]	I <sup>2</sup> C Slave	SPI slave	Built-in oscillator [Hz]	Tempera ture sensor	Power on reset	Boosting circuit	Package (Form of delivery)
S1D14F57	256 (2TP/2BP)	1.75 to 5.5	9.15 /12.30 /15.45	16K ※1	1	1	1M	1	1	1	Chip

%1: During erasing / programming voltage in flash memory (VPP): The external applying of 7.0V / 7.0V(Typ.) is needed.

### S1C17800 series (High-performance models)

The 16-bit RISC MCUs allowing the 32-bit level sophisticated processing to perform. The device having the LCDC can display the 1-bpp maximum VGA monochrome images. Also, the device integrates a wide variety of interfaces such as USB, UART, SPI, I<sup>2</sup>C, I<sup>2</sup>S, A/D converter, and remote control interfaces, and it can improve the user interface of various home appliances (for example, the washing machines, rice cookers, and coffee makers) that use the display, music, voice, touch panel and other interfaces.

	Display	Op	peration cl	ock	Supply current		N	/lemo	ry	I/O			Tir	mer					SIO				ít	ít			
Products	LCD Driver segxcom	High speed [Hz] (Max.)	Low speed [Hz] (Typ.)	Built-in oscillator [Hz] (Typ.)	Sleep/ Halt/ operating (32K)/ operating (1M) [µA] (Typ.)	Supply voltage [V]	Flash ROM [Bvte]	Mask ROM [Bvte]	RAM [Byte]	I/O port %6	8-bit	16-bit	16-bit PWM	Stopwatch	Clock	Real Time Clock	UART	SPI	I <sup>2</sup> C master	I <sup>2</sup> C slave	Remote control circuit	Sound generator	R/F converter, 24-bit	A/D converter, 10-bit	Multiplier/Divider	SVD 355	Other functions, Package (Form of delivery)
S1C17801	LCD controller	48M	32.768k	_	1.4%2/ 12 /—/ 6000	3.0 to 3.6	128K ※4	_	4K	I :8 I/O :91	6	2	1 -	_ 1	_	1 ※1	1	2	1	_	1	_	_	8	Multiplier:1 Divider:-		Supported bus, USB, TQFP15-128
S1C17803	LCD controller	33M	32.768k		1.3%2/ 5	2.7 to 5.5	128K ※4		16K	I: 4 I/O :93	4	1	2 -	_ 1		1		2			1	_		4	1		Supported bus, TQFP15-128
31017603					/ <u>    /</u> 6500	2.7 10 5.5	*4			I: 3 I/O :66	4		2			*1	1	2 ※3	1	1				4			TQFP14-100

×1: The battery backed up operation is supported.

\*2: Unmounted OSC1.

\*3: Universal Serial Interface (One is selected from UART/SPI/I<sup>2</sup>C).

×4: This product uses SuperFlash® technology licensed from SST UK Ltd.

\*5: SVD is an abbreviation for Supply Voltage Detector.

\*6: Including Input port and Output port.

# 2-2 Arm<sup>®</sup> Cortex<sup>®</sup>-M0+ 32-bit Microcontrollers

# 32-bit RISC

Microcontrollers S1C31 Family Arm<sup>®</sup> Cortex<sup>®</sup>-M0+ microcontroller

The S1C31 Family is a 32-bit microcontroller which adopts the Arm® Cortex®-M0+ processor for the CPU core with several built-in features, such as various timers, serial interface functions, LCD driver, memory display controller, USB controller and Flash memory in one chip.

The S1C31 Family constructed and manufactured with the exceedingly energy efficient Cortex®-M0+ processor, Epson's original super-low leak process and circuit technology, contributes to exceptional performance of various mobile devices and sensor node terminals which perform environmental measurements over a long period while extending battery life.

### S1C31D00 series

This series is a 32-bit MCU with an Arm<sup>®</sup> Cortex<sup>®</sup>-M0+ processor included that features low-power operation.

It incorporates a lot of serial interface circuits, a memory display controller, and a voltage booster for memory display. This MCU is suitable for various kinds of battery-driven controller applications.

	Display		Operatio	on clock	Supply current		Mem	ory	I/O		Tin	ner				SIO			it	ij			Ŀ	
Products	Controller	High speed [Hz] (Max.)	Low speed [Hz] (Typ.)	Built-in oscillator [Hz] (Typ.)	Sleep/ Halt/ operating (32K)/ operating (1M) [µA] (Typ.)	Supply voltage [V]	Flash ROM [Byte]	RAM [Byte]	I/O port ※6	16-bit	16-bit PWM	WDT	Real Time Clock	UART	SPI	QSPI	- - - - -	IK remote control circuit	Sound generator R/F converter. 24-b	A/D converter, 12-bit	DMA	USB	SVD %5 Temperature sensor	Package (Form of delivery)
S1C31D01	MDC ※1	21M	32.768k	32k/1M/2M/8M/ 12M/16M/20M	0.46/1.7/ 10/250	1.8 to 5.5 %2,3	256K ※4	96K	57	8	2×6	1	1	3	2	1	2	1	1 -	7	4	2.0FS Dev	1 1	Chip WCSP-96 TQFP14-80 VFBGA5H-81
S1C31D50/51	_	16M	32.768k	32k/4M/8M/ 16M	0.46/1.8/ 10/250	1.8 to 5.5 ※2,3	192K ※4	8K	39 55 71 91	8	2×4	1	1	3	3	1	3	1	- 1	5 7 8 8	4	_	1 -	TQFP12-48 QFP13-64 TQFP14-80 QFP15-100
S1C31D41	-	16M	32.728k	32k/4M/8M/ 16M	TBD	1.8 to 5.5v	96K	8K	25 39 55	8	2×4	1	1	3	3	1	3	1	- 1	6 7 8	5	_	1 1	TQFP12-32 TQFP12-48 TQFP13-64

\*1: MDC is an abbreviation for Memory Display Controller.
 \*2: During erasing / programming in flash memory (Voo): 2.7 to 3.6V (without the external VPP applying), 2.4 to 3.6V (during the external VPP applying)

\*3: LCD operation (VDD): 2.5 to 3.6V

\*4: Flash memory could be erased/programmed by internal power as well.

×5: SVD is an abbreviation for Supply Voltage Detector×6: Including Input port and Output port.

### S1C31W00 series

This series is a 32-bit MCU with an Arm<sup>®</sup> Cortex<sup>®</sup>-M0+ processor included that features low-power operation.

It incorporates a lot of serial interface circuits and LCD driver. It is suitable for various kinds of battery-driven controller applications

	A100 0. 10				,											<u> </u>		0 0							
	Display		Operatio	on clock	Supply current		Mem	nory	I/O		Tir	ner				SIC	)			pit				nsor	
Products	LCD Driver segxcom	High speed [Hz] (Max.)	Low speed [Hz] (Typ.)	Built-in oscillator [Hz] (Typ.)	Sleep/ Halt/ operating 32K)/ operating (1M) [µA] (Typ.)	Supply voltage [V]	Flash ROM [Byte]	RAM [Byte]	I/O port %5	16-bit	16-bit PWM	WDT	Real Time Clock	UART	SPI	QSPI	I <sup>2</sup> C	IR remote control circuit	und generato	A/D converter, 12-bit	DMA	USB	SVD %4	0	Other specification, Package (Form of delivery)
S1C31W65	52×8 56×4	33M	32.768k	1M/2M/8M/ 12M/16M/24M/ 32M/32k	0.3/1.5/195	1.8 to 5.5 ※6	128K ※3	16K	64	8	3×4	1	1	2	2	-	2	1	1	1 7	4	-	1	1	Maximum operating temperature 105°C,TQFP14-100
S1C31W73	96×16 88×24 80×32	33M	32.768k	1M/2M/8M/ 12M/16M/24M/ 32M/32k	0.7/2.0/214	1.8 to 5.5 ※6	384K ※3	32K	73	8	2×4	1	1	2	2	1	2	1	1	7	4	2.0FS Dev	1	1	Maximum operating temperature 105°C,QFP21-216, Chip
S1C31W74	88 x 16 80 x 24 72 x 32	21M	32.768k	1M/2M/8M/ 12M/16M/20M	0.4/1.7/ 10/250	1.8 to 3.6 ※1,2	512K ※3	128K	71	4	2x2	1	1	2	1	-	2	1	1	ı –	4	2.0FS Dev	2	-	Chip VFBGA8H-181

×1: During erasing / programming in flash memory (Vob): 2.7 to 3.6V (without the external VPP applying), 2.4 to 3.6V (during the external VPP applying)

\*2: LCD operation (Vpp): 2.5 to 3.6V

\*3: Flash memory could be erased/programmed by internal power as well.
 \*4: SVD is an abbreviation for Supply Voltage Detector.

\*5: Including Input port and Output port.

\*6: During erasing / programming in flash memory(VDD): 2.2V to 5.5V.

3

Page S1D13\*\*\* series LCD controller 20 Simple LCD Controller S1D13L\*\* series 21 LCD controller with Camera I/F S1D13\*\*\* series 21 Display controllers Memory Display Controller S1D13C00 series 21 LCD controller for automotive S2D13\*\*\* series 22 In-vehicle multi-Camera interface IC S2D13P04 series 22 Speech & Audio S1V3\*\*\* series 23 Thermal-head drivers S1D50000 series 24 EPD drivers S1D14F00 series 25 USB Controller S2R72A\*\* series 25 USB bus switch ICs S1F773\*\* series 25

**ASSPs** 



# 3-1 Display controllers

Our LCD controllers feature high performance, low power consumption which was achieved by applying an original architecture based on our own "saving technology". These LCD controllers can be used on a variety of CPUs. Since the product line-up listed below allows to support a wide range of LCD panels, including those from small to large scale and those from monochrome to color, these controllers are best suited to mobile devices, OA devices, FA devices and vehicle-mounted devices.

### LCD Interface Support Supply Voltage Color Depth (Max.) External Memory Capacity Internal Mono-chrome STN Additional features CPU Interface Memory Capacity Products Package Typical resolution Support Color STN TFT Core 10 8-bit I/F 16 grayscale 3 overlay screens 32KB, SRAM 3.0V to 3.6V 3.0V to 5.5V Direct addressing Indirect addressing S1D13700F02A 4-bit n/a n/a QVGA n/a TQFP13-64 MSTN: 16 8-bit I/F 16 grayscale CSTN: 256 colors TFT: 256 colors MSTN: 64 grayscale 9-bit / 12-bit 80KB, SRAM (with external logic) 16-bit I/F, 2.7V to 3.6V 2.7V to 5.5V S1D13705F00A 4-bit / 8-bit 4-bit / 8-bit QVGA n/a SwivelView QFP14-80 Direct addressing 8-bit I/F 9-bit / grayscale CSTN: SwivelView (with external logic), 16-bit I/F. 4-bit / 8-bit / 16-bit 80KB, SRAM 1.8V to 3.6V 1.8V to 3.6V 12-bit / 18-bit Picture in picture S1D13706F00A 4-bit / 8-bit QVGA n/a TQFP15-100 64K colors TFT: 64K colors Direct addressing MSTN: 16 8-bit I/F Direct addressing grayscale TFT: 3.0V to 5.5V 3.0V to 5.5V S1D13709F00A 4-bit mono 32KB, SRAM 3 overlay TQFP14-80 QVGA 4-bit n/a n/a 6-bit color screens Indirect addressing 64 colors 1.4V to 8-bit /16-bit I/F 256K 768KB 1.65V to S1D13742F01A QFP20-144 n/a n/a 18-bit VGA 768KB, SRAM 464KB, SRAM 1024KB, SRAM 1024KB, n/a 1.4V to 1.6V 1.4V to 1.6V 1.35V to 1.65V 1.35V to 1.65V to 3.60V 1.65V to 3.60V 1.62V to 3.60V 1.62V to SwivelView Indirect addressing 8-bit /16-bit I/F Indirect addressing 16-bit I/F, colors 18-bit / 24-bit 18-bit / 24-bit 18-bit / S1D13743F00A WQVGA 16M colors SwivelView QFP20-144 n/a n/a n/a Picture in S1D13748F00A n/a n/a WVGA 64K colors n/a QFP20-144 Indirect addressing 16-bit I/F, picture Picture in S1D13748B00B WVGA 64K colors n/a n/a n/a PEBGA10L-121 Indirect addressing 24-bit SRAM 1.65V 3.60V picture MSTN: 64 8-bit / 16-bit I/F grayscale CSTN: 16-bit / 18-bit / 24-bit PinP 384KB, SRAM S1D13781F00A Direct addressing 8-bit / 16-bit 1.35V to 1.65V 1.62V to 3.60V QFP15-100 4-bit / 8-bit WQVGA n/a α-Blend, 2D BitBLT Indirect addressing, SPI 64K colors TFT: 16M colors MSTN: 64 grayscale CSTN: 8-bit I/F (with external logic) 16-bit I/F, 2D BitBLT, 9-bit / 4-bit / 8-bit 3.0V to 3.6V 160KB, SRAM 1.8V to 2.75V S1D13A04F00A QVGA SwivelView USB client TQFP15-128 4-bit / 8-bit 12-bit / 18-bit n/a / 16-bit 64K colors TFT: Direct addressing 1.1 64K colors MSTN: 64 8-bit I/F (with external logic) 16-bit I/F, 2D BitBLT, 9-bit / 12-bit / 18-bit grayscale CSTN: 4-bit / 8-bit 160KB, SRAM 3.0V to SwivelView USB client 1.1 1.8V to 2.75V S1D13A04B00B 4-bit / 8-bit QVGA PFBGA10U-121 n/a 64K colors TFT: 64K colors 64K colors 64 / 16-bit 3.6V Direct addressing 8-bit I/F (with external logic) 16-bit I/F, 2D BitBLT, grayscale CSTN: 9-bit / 4-bit / 8-bit 256KB, SRAM 1.8V to 2.75V 3.0V to SwivelView S1D13A05B00B QVGA 4-bit / 8-bit 12-bit / 18-bit n/a PFBGA10U-121 USB client 1.1 / 16-bit 3.6V 64K colors TFT: Direct addressing 64K colors MSTN: 64 grayscale CSTN: 256K 16-bit I/F Up to 16MB Direct addressing, 1.65V to 2D Sprite, 2D BitBLT 3.0V to S1D13513F01A QFP22-208 8-bit 8-bit 18-bit XGA n/a Indirect addressing 1.95V 3.6V colors SDRAM Serial I/F TFT: 256K colors MSTN: 64 grayscale CSTN: 256K 16-bit I/F Up to 64MB Direct addressing 18-bit / 1.65V to 3.0V to 2D Sprite S1D13513B01B XGA 8-bit 8-bit n/a PBGA1UC256 Indirect addressing 24-bit 1.95V 3.6V 2D BitBLT colors TFT: SDRAM Serial I/F 16M colors Up to 16MB SDRAM Picture in 18-bit / 24-bit 8-bit /16-bit I/F 2.3V to 2.7V 3.0V to 3.6V S1D13517F00A SVGA 16M colors picture α-Blend QFP15-128 n/a n/a n/a Indirect addressing Up to 16MB 18-bit / 24-bit 1.65V to 1.95V PinP $\alpha$ -Blend 3.0V to 3.6V S1D13U11F00A USB2.0 HS n/a SVGA 16M colors n/a QFP20-144 n/a SDRAM

# LCD controller

# Application Specific Standard Products

# Simple LCD Controller

		[	LCD Interf	ace Suppor	t		Internal	External	Supply	/ Voltage		
Products	CPU Interface Support	Mono- chrome STN	Color STN	TFT	Typical Resolution	Color Depth (Max.)	Memory Capacity	Memory Capacity	Core	Ю	Additional features	Package
S1D13L01F00A	8-bit / 16-bit I/F, Direct Addressing, Indirect Addressing, SPI,	n/a	n/a	16-bit / 18-bit / 24-bit	WQVGA	16M colors	384KB SRAM	n/a	1.35V to 1.65V	1.62V to 3.6V	Picture in Picture	QFP15-128
S1D13L02F00A	16-bit I/F, Indirect Addressing	n/a	n/a	18-bit / 24-bit	WVGA	16M colors	1024KB, SRAM	n/a	1.35V to 1.65V	1.62V to 3.6V	Picture in Picture	QFP22-208
S1D13L03F00A	8-bit / 16-bit I/F, Indirect Addressing	n/a	n/a	18-bit	WVGA	256K colors	768KB SRAM	n/a	1.4V to 1.6V	1.65V to 3.6V	n/a	QFP21-176
S1D13L04F00A	16-bit I/F, Direct Addressing, Indirect Addressing, Serial I/F	n/a	n/a	18-bit	XGA	256K colors	n/a	Up to 16MB, SDRAM	1.65V to 1.95V	3.0V to 3.6V	Picture in Picture, Alpha Blend	QFP22-208

# LCD controller with Camera I/F

Products	CPU Interface Support	Mono- chrome	CD Interf Color STN	ace Supp	ort Typical resolution	Color Depth (Max.)	Internal Memory Capacity	External Memory Capacity	Camera (pixel)	JPEG Codec	Supply Core	Voltage IO	Additional features	Package
		STN	311		resolution		Oupdoily	Ocipciony						
S1D13515F00A	16-bit I/F, Direct addressing, Indirect addressing, Serial I/F	n/a	n/a	18-bit / 24-bit	XGA	16M colors	n/a	Up to 64MB SDRAM	0.3MP	n/a	1.65V to 1.95V	3.0V to 3.6V	Prewarping Embedded RISC CPU	QFP22-256
S1D13719B00B	16-bit I/F, Direct addressing, Indirect addressing	n/a	n/a	18-bit / 24-bit	QVGA	16M colors	512KB, SRAM	n/a	2.0MP	Encode/ Decode	1.65V to 1.95V	2.30V to 3.25V	2D BitBLT, SwivelView, SD memory card I/F	PFBGA10U-180

# Memory Display Controller

Products	CPU Interface Support	Panel Interface Support	Color Depth (Max.)	Internal Memory Capacity	Supply Voltage	Additional Features	Package
S1D13C00F00C S1D13C00B00C	SPI, QSPI, Indirect 8-bit	6-bit color MIP, 3-bit or 1-bit Memory LCD with SPI	64 colors	96KB	1.8V to 5.5V	RTC, SPI, QSPI, I <sup>2</sup> C, DMAC, Sound Generator, IR remote control transmitter	TQFP13-64 WCSP64

# ■LCD controller for automotive

		LC	CD Interf	face Supp	ort	Color	Internal	External			Supply '	Voltage			
Products	CPU Interface Support	Mono- chrome STN	Color STN	TFT	Typical resolution	Depth (Max.)	Memory Capacity	Memory Capacity	Camera (pixel)	JPEG Codec	Core	ю	Temp. Range	Additional features	Package
S2D13515F00A	16-bit I/F, Direct addressing, Indirect addressing, Serial I/F	n/a	n/a	18-bit / 24-bit	XGA	16M colors	0	Up to 64MB SDRAM	0.3MP	n/a	1.65V to 1.95V	3.0V to 3.6V	-40 to 105°C	Prewarping Embedded RISC CPU	QFP22-256
S2D13719F00A	16-bit I/F, Direct addressing, Indirect addressing	n/a	n/a	18-bit / 24-bit	QVGA	16M colors	512KB, SRAM	n/a	2.0MP	Encod e/ Decod e	1.65V to 1.95V	2.3V to 3.6V	-40 to 105°C	2D BitBLT, SwivelView, SD memory card I/F	QFP22-208

# ■In-vehicle multi-camera interface IC

Products	Supported CPU interface	Function	Operating		Supply voltage		Package
Tioddola	Supported Of O Internace	T diredori	temperature range	Core	10	Analog signals	T ackage
S2D13P04F00A	l²C SPI	Including four channels of NTSC/PAL decoders 8-bit digital output (supporting ITU-R BT656) Equipped with multi-image synthesis mode Distortion correction function	-40°C to +85°C	1.65V to 1.95V	3.0V to 3.6V	3.0V to 3.6V	QFP15-100
S2D13P04B00B	I <sup>2</sup> C SPI	Including four channels of NTSC/PAL decoders 8-bit digital output (supporting ITU-R BT656) Equipped with multi-image synthesis mode Distortion correction function	-40°C to +85°C	1.65V to 1.95V	3.0V to 3.6V	3.0V to 3.6V	PFBGA10U-121
S2S65P10F00A	I <sup>2</sup> C	8-bit digital output (supporting ITU-R BT656) Equipped with multi-image synthesis mode	-40°C to +105°C	1.8V±0.15V	2.4V to 3.6V	—	QFP15-100

# 3-2 Speech & Audio

# Speech & Audio

Products	Supply voltage (V)	Additional features	Package
S1V3G340F00A		•Epson high quality codec format •Sampling Frequency 16KHz	QFP13-52
S1V3G340F01A	2.2 to 5.5V	-Bit rate <sup>−</sup> 40k, 32k, 24k, 16kbps +High Quality 16-bit mono DAC •SPI Slave / I <sup>2</sup> C / UART	QFP12-48
S1V3G340F02A		•Clock Frequency 32.768KHz(Oscillator, external clock) , 12.288MHz(external clock) •external SPI-Flash I/F	SQFN7-48
S1V30080F0*A	2.2 to 5.5V	•Epson high quality codec format(Built in ROM for Voice data) •5ch, 5octave Melody Synthesizer integrated •Mixing function support •Sampling frequency 16K, 8KHz •10-bit mono DAC integrated	QFP12-48
S1V30080F1*A	2.2 10 3.3 V	Standalone interface / SPI Slave / I <sup>2</sup> C     Clock Frequency 8.192MHz(fs:8KHz), 16.384MHz(fs:16KHz)     × F00 for external clock     × F11 for Oscillator	QFP13-52

# 3-3 Thermal-head Drivers

# ■ Thermal-head drivers

Products	Logic supply voltage range V	Output withstand voltage V (Max.)	Output current mA (Max.)	Clock frequency MHz (Max.) [#]	Number of driver outputs	Description	Package
S1D53230D0A0	3.3 / 5 ±10%	50	10 / 13	35[12 / 16]	128	One side output 400dpi	Bare Chip
S1D56200D0A0	5±10%	32	70	7 [6]	64	One side output 200dpi	
S1D56220D0A0	3 / 3.3 / 5 ±10%	9	60	7[5] / 7[5] / 10[8]	64	One side output 200dpi, Battery Use	
S1D56240D0A0	3.3 / 5 ±10%	10	60	4[3] / 10[8]	64	One side output 200dpi, Battery Use	
S1D56520D0A0	3.3 / 5 ±10%	32	10 / 13.5	30	128	One side output 300dpi	
S1D56540D0A0	- 3.37 J I 10%	52	50	16[12 / 16]	120	One side odiput Soodpi	
S1D56570D0A0	2.2 / 5 1400/	32	50	12/16[12 / 16]	64	One side sutnut 200dni	
S1D56580D0A0	3.3 / 5 ±10%	32	50	16/20[12 / 16]	96	One side output 300dpi	
S1D56700D0A0			50	40.501	04	300dpi 3-step latch Heat history control	
S1D56710D0A0	5±10%	32	50	10 [8]	64	300dpi 5-step latch Heat history control	
S1D56730D0A0	1		15	16 [16]	128	600dpi 5-step latch Heat history control	

# : In case of cascade connection

# 3-4 EPD drivers

# Segment type EPD drivers

The S1D14F00 series is EPD driver ICs that is good for a segment type E-paper with small display capacity. These driver ICs can expand the segment display domain when coupled with the S1C17F00 that is 16-bit MCU embedded EPD drivers. This combination has high efficiency of battery power to meet E-paper characteristics.

### S1D14F00 series

Products	Supply voltage range (V)	EPD voltage range (V)	Driver output Segment (TP/BP)	Flash (bit)	Command Interface	Built-in oscillator [MHz]	Package	Remarks
S1D14F57	1.75 to 5.5	9.15/12. 30/15.45	256 (2TP/2BP)	16k (Note1)	I <sup>2</sup> C Slave SPI Slave	2	Bare Chip	Built-in power circuit for EPD Temperature Sensor Power on Reset
S1D14F61	2.0 to 3.6	9/12/15	32 (1TP/1BP)	_	I <sup>2</sup> C Slave SPI Slave	_	QFP14-80	Built-in EPD controller Extended function for S1C17F57

Note1: During programming in flash memory 7.0V(Typ)

# 3-5 USB Controller & USB bus switch ICs

# USB HUB Controller

Product	Supply voltage (V)	Features	Package
S2R72A42F12C S2R72A43F12C S2R72A44F12C S2R72A44F12C	3.3/1.8	<ul> <li>S2R72A42 • High Speed x 2 Down Stream Port</li> <li>S2R72A43 • High Speed x 2 Down Stream Port + Full Speed x 1 Down Stream Port</li> <li>S2R72A44 • High Speed x 2 Down Stream Port + Full Speed x 2 Down Stream Port</li> <li>Operating temperature range -40°C to + 105°C</li> <li>For automotive applications. Supporting AEC-Q100. (QFP12-48)</li> </ul>	QFP12-48 QFN7-48
S2R72A54F12E	3.0V to 3.6V	<ul> <li>High Speed x 4 Down Stream Port</li> <li>Operating temperature range -40°C to + 105°C</li> <li>For automotive applications. Supporting AEC-Q100. (QFP12-48)</li> </ul>	QFP12-48 SQFN6-36

# USB Re-Synchronization IC

Product	Supply voltage (V)	Features	Package
S2R72A11F05E	3.3V to 3.6V	<ul> <li>Excellent data communication characteristics of HS (480Mbps)</li> <li>Automatic USB line monitor and control function</li> <li>Operating temperature range -40°C to + 105°C</li> <li>For automotive applications. Supporting AEC-Q100.</li> </ul>	SQFN5-32

# ■ USB bus switch ICs

		Operational						
Products	Input voltage range	power consumption	Static current	ON Resistance	Pin ca	apacity	PKG	
S1F77310M0A	3.0V to 3.6V	14μA (Max.)	1μΑ (Max.)	5.3Ω (Typ.)	1.7 pF	1.7 pF (Typ.)		
S1F77330B0A	3.0V to 3.6V	14μA (Max.)	1μΑ (Max.)	6.0Ω (Тур.)	D-system: 2.7 pF (Typ.)	D*-system: 1.45 pF (Typ.)	WCSP (10balls)	
S1F77330M0A	3.0V to 3.6V	14μA (Max.)	1μA (Max.)	6.0Ω (Typ.)	D-system: 2.7 pF (Typ.)	D*-system: 1.45 pF (Typ.)	PLP062725A-10PIN	

Note: D-system having DX and DY pins, and D\*-system having D1X, D1Y, D2X and D2Y pins

# REAL TIME CLOCK MODUL

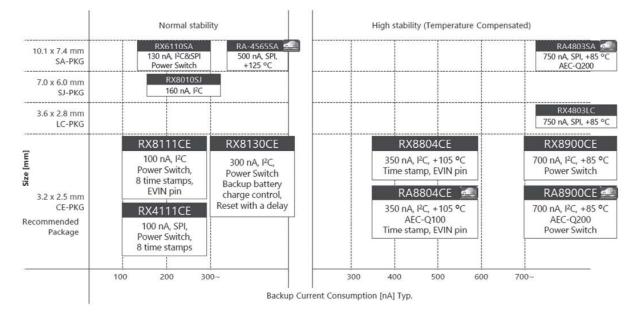
Page

Features and Functions	28
3.2 x 2.5 x 1.0t (CE package) Recommendation package	28
3.6 x 2.8 x 1.2t (LC package / VSOJ-12 pin)	29
6.3 x 5.2 x 1.4t (NB package / SON-22 pin)	29
7.0 x 6.0 x 2.65t (SJ package / SOP-8 pin)	29
7.3 x 6.2 x 1.5t (JE package / VSOJ-20pin)	29
10.1 x 7.4 x 3.3t (SA package / SOP-14 pin)	30
10.2 x 7.8 x 2.0t (SF package / SSOP-24 pin)	30
16.3 x 12.2 x 2.8t (SOP-24 pin)	30

# 4-1 Real Time Clock modules (RTC modules)

Epson's crystal integrated RTC modules offer variety of features such as lower power, accurate clock/date information, Wake-up Timer, Power Switch, and Time-Stamp function. This will help your system lower power with multi-functionality. Features

- Our lower power design enables our RTC modules to store abnormality on system and time errors even when the main MCU is not in operation
- Tuning Folk Crystal unit and DTCXO (Some products only) integrated RTC modules can assure and manage time information with higher accuracy



### **Features and Functions**

Category	Summary	Use case recommendations, etc
Frequency Tolerance	The variance based on 32.768 kHz under the operating temperature on the integrated crystal inside. For an RTC module, $\pm 23 \times 10^{-6}$ approximately equals to 1 minute per month. Crystal unit inside has a quadratic curve whose peak temperature stays at a room temperature. Therefore, time accuracy varies depending on the external temperature. Epson also offers temperature compensated RTC modules whose timing has been already adjusted within the operating temperature.	Temperature compensated models are suitable when -your system will be installed outside or a hotter place where the temperature may change drastically. -your system needs time accuracy with a standalone condition (Best accuracy option: $\pm 3.4 \times 10^{-6} \div 9$ seconds per month)
Backup current consumption	Consumption value when RTC module is individually in operation, whereas the system's main MCU is on sleep mode. " Max." shows the maximum value within the operating temperature (Ta).	Lower power RTC modules are suitable for - your system that operates with a battery. - your system that goes to sleep-mode for a long period Our low power RTC modules can manage time information or system behavior for a long term.
Time-Stamp function	This stores the time data when an event occurs. Time-stamp functions followed by several triggers. For products with EVIN pin, triggers interlock with EVIN pin inputs. For products without EVIN pin, triggers interlock with RTC module's internal operation or Bus access.	RTC modules with time-stamp are suitable for applications such as - anti-tampering for smart meters or security systems - abnormality detection for factory automation
Power Switch	This monitors the main power condition, and this will automatically change the power source to back-up mode when the voltage on the main power reduces. Please refer to application manuals for details since functions vary depending on each product.	By simplifying Diode-OR circuit, it will help reduce a leak current, as well as utilize an engineering resource and PCB area.

3.2 x 2.5 x 1.0t (	CE package) Recommendation package

					Specification	ons								
Model	Interface	Operating temperature Ta [°C]		Frequency Tolerance [x 10 <sup>-6</sup> ]			Backup current consumption [µA] 3.0V		Functions					
		Min.	Max.	+25 °C	-40 °C to +85 °C	-40 °C to +105 °C	Typ. (25 °C)	Max. (Ta=Max.)	Time Stamp	Power Switch	EVIN pin	User Memory	Timer	Others
RX8111CE	I <sup>2</sup> C	-40	+85	±11.5			0.1	0.45	8	1	1	512-bit	24-bit x 1 ch. to 32 years	
RX4111CE	SPI	-40	+85	±23.0	-	-	0.1	0.45	8	1	-	512-bit	24-bit x 1 ch. to 32 years	
RX8804CE	I <sup>2</sup> C	-40	+105	-	±3.4 ±5.0	±8.0	0.35	1.5	1	-	1	-	16-bit x 1ch. to 7.5 years	SOUT pin
RX8130CE	l <sup>2</sup> C	-40	+85	5±23	-	-	0.3	0.5	-	1	-	-	16-bit x 1 ch. to 7.5 years	Backup battery charge control, Reset output with Delay
RX8900CE	I <sup>2</sup> C	-40	+85			-	0.7	1.4	-	1	-	-	12-bit x 1ch. to 2.8 days	Built-in Temp. Sensor
RA8804CE (AEC-Q100)	I <sup>2</sup> C	-40	+105	-	±3.4 ±5.0	±8.0	0.35	1.5	1	-	1	-	16-bit x 1ch. to 7.5 years	SOUT pin
RA8900CE (AEC-Q200)	l <sup>2</sup> C	-40	+85			-	0.7	1.4	-	1	-	-	12-bit x 1ch. to 2.8 days	Built-in Temp. Sensor

# 3.6 x 2.8 x 1.2t (LC package / VSOJ-12 pin)

					Specification	ons													
Model	Interface	Operating temperature Ta [°C]		ture Frequency Toleral		ce [x 10 <sup>-6</sup> ]	[x 10 <sup>-6</sup> ] Backup current consumption [µA] 3.0V		Functions										
		Min. Max	Max.	+25 °C	-40 °C to +85 °C	-40 °C to +105 °C	Typ. (25 °C)	Max. (Ta=Max.)	Time Stamp	Power Switch	EVIN pin	User Memory	Timer	Others					
RX-8803LC	I <sup>2</sup> C				±3.4		0.75	2.1	-	-	1	-	to 2.8 days	Time sync. with 1 PPS					
RX-4803LC	SPI			-	±5.0		0.75	2.1	-	-	1	-	to 2.8 days	Time sync. with 1 PPS					
RX-8035LC	I <sup>2</sup> C								5±23 5±5			0.4	1.2	4		1	-	-	
RX-4035LC	SPI			5±5 0±5			0.4	1.2			1	-	-						
RX-8731LC	I <sup>2</sup> C	-40	+85	+85	+85	+85		-	-	0.35	1.4	-	-	-	EEPROM: 80-bit ID-ROM: 48-bit	to 2.8 days			
RX-8571LC	I <sup>2</sup> C			5±23			0.22	0.4	-	-	-	128-bit	to 7.5 years	DAS pin					
RX-4571LC	SPI						0.32	0.95	-	-	-	-	to 2.8 days						
RX-8564LC	I <sup>2</sup> C						0.275	0.7	-	-	-	-	to 255 min.						

\_\_\_\_\_

# 6.3 x 5.2 x 1.4t (NB package / SON-22 pin)

					Specificatio	ons								
Model	Interface	Operating temperature Ta [°C]		Frequency Tolerance [x 10 <sup>-6</sup> ]			Backup current consumption [µA] 3.0V		Functions					
		Min.	Max.	+25 °C	-40 °C to +85 °C	-40 °C to +105 °C	Typ. (25 °C)	Max. (Ta=Max.)	Time Stamp	Power Switch	EVIN pin	User Memory	Timer	Others
RX-8025NB	I <sup>2</sup> C			5±5			0.48	1.2	-	-	-	-	-	
RX-4045NB	SPI			0±5		-	0.48	1.2	-	-	-	-	-	
RX-8571NB	I <sup>2</sup> C						0.2	0.4	-	-	-	128-bit	to 7.5 years	DAS pin
RX-4571NB	SPI	-40	+85		-		0.32	0.95	-	-	-	-	to 2.8 days	
RTC-4574NB	SPI			5±23			0.5	1.0	-	-	-	-	to 255 min.	
RTC-8564NB	I <sup>2</sup> C						0.275	0.7	-	-	-	-	to 255 min.	
RX-8581NB	I <sup>2</sup> C					i İ	0.45	0.8	-	-	-	-	to 2.8 days.	

# 7.0 x 6.0 x 2.65t (SJ package / SOP-8 pin)

					Specificatio	ons									
Model	Interface	Ce Operating temperature Ta [°C]		Frequency Tolerance [x 10 <sup>-6</sup> ]			Backup current consumption [µA] 3.0V		Functions						
		Min.	Max.	+25 °C	-40 °C to +85 °C	-40 °C to +105 °C	Typ. (25 °C)	Max. (Ta=Max.)	Time Stamp	Power Switch	EVIN pin	User Memory	Timer	Others	
RX8010SJ	I <sup>2</sup> C	-40	+85	5±23	-	-	0.16	0.32	-	-	-	128-bit	to 7.5 years	Common pin connection with SOP-8	

# 7.3 x 6.2 x 1.5t (JE package / VSOJ-20pin)

					Specification	ons								
Model Interface	Interface	Operating temperature Ta [°C]		Frequency Tolerance [x 10 <sup>-6</sup> ]			Backup current consumption [µA] 3.0V		Functions					
		Min.	Max.	+25 °C	-40 °C to +85 °C	-40 °C to +105 °C	Typ. (25 °C)	Max. (Ta=Max.)	Time Stamp	Power Switch	EVIN pin	User Memory	Timer	Others
RTC-4574JE	SPI						0.5	1.0	-	-	-	-	to 255 min.	
RTC-8564JE	I <sup>2</sup> C	-40	+85	5±23	-	-	0.275	0.7	-	-	-	-	to 255 min.	
RX-8581JE	I <sup>2</sup> C						0.45	0.8	-	-	-	-	to 2.8 days	

# Real Time Clock Modul

# 10.1 x 7.4 x 3.3t (SA package / SOP-14 pin)

					Specificatio	ons								
Model	Interface	Oper tempe Ta [	rature	Freque	ncy Tolerano	ce [x 10 <sup>-6</sup> ]	consum	p current ption [µA] .0V				Funct	ions	
		Min.	Max.	+25 °C	-40 °C to +85 °C	-40 °C to +105 °C	Тур. (25 °С)	Max. (Ta=Max.)	Time Stamp	Power Switch	EVIN pin	User Memory	Timer	Others
RX6110SA	SPI & I <sup>2</sup> C			5±23	-		0.16	0.32	-	1	-	128-bit	to 7.5 years	
RX8900SA	I <sup>2</sup> C						0.7	1.4	-	1	-	-	to 2.8 days	Built-in Temp. Sensor
RX-8803SA	I <sup>2</sup> C			-	±3.4 ±5.0		0.75	2.1		-	1		to 2.8 days	Time sync. with 1 PPS
RX-4803SA	SPI						0.75	2.1	-	-	1		to 2.8 days	Time sync. with 1 PPS
RX-8035SA	I <sup>2</sup> C			5±23 5±5			0.35	1.2	1	1	2	-	-	
RX-4035SA	SPI			0±5			0.35	1.2	1	1	2	-	-	
RX-8025SA	I <sup>2</sup> C			5±5	1		0.48	1.2	-	-	-	-	-	
RX-4045SA	SPI	-40	+85	0±5	-	-	0.48	1.2	-	-	-	-	-	
RX-8571SA	I <sup>2</sup> C			5±23			0.2	0.4	-	-	-	128-bit	to 7.5 years	DAS pin
RX-4571SA	SPI			5±23			0.32	0.95	-	-	-	-	to 2.8 days	
RA8803SA (AEC-Q200)	I <sup>2</sup> C				±3.4		0.75	2.1	-	-	1	-	to 2.8 days	Time sync. with 1 PPS
RA4803SA (AEC-Q200)	SPI			-	±5.0		0.75	2.1	-	-	1	-	to 2.8 days	Time sync. with 1 PPS
RA-8565SA (AEC-Q200)	I <sup>2</sup> C			5±23			1.0	1.6	-	-	-	-	to 255 min.	
RA-4565SA (AEC-Q200)	SPI			5±23	-		0.8	1.6	-	-	-	-	to 255 min.	

# 10.2 x 7.8 x 2.0t (SF package / SSOP-24 pin)

		Specifications													
Model	Interface	Operating temperature Ta [°C]		Frequency Tolerance [x 10 <sup>-6</sup> ]		Backup current consumption [µA] 3.0V		Functions							
		Min.	Max.	+25 °C	-40 °C to +85 °C	-40 °C to +105 °C	Typ. (25 °C)	Max. (Ta=Max.)	Time Stamp	Power Switch	EVIN pin	User Memory	Timer	Others	
RTC-7301SF	Parallel	-40	+85	5±23	-	-	0.6	1.0	1.0 to 255 min. Built-in Temp. Sensor						

# 16.3 x 12.2 x 2.8t (SOP-24 pin)

		Specifications												
Model	Interface	Operating temperature Ta [°C]		Frequency Tolerance [x 10 <sup>-6</sup> ]		consum	Backup current onsumption [µA]		Functions					
						5.0V								
		Min.	Max.	+25 °C	-40 °C to +85 °C	-40 °C to	Typ.	Max. (Ta=Max.)	Time Stamp	Power Switch	EVIN pin	User Memorv	Timer	Others
					105 0	+105 0	(23 0)		Stamp	Switch	pin	wentury		
RTC-72423	Parallel	-40	+85	±20	-	-	1.0	10	-	-	-	-	-	

# 5

Package

Information

PFBGA

WCSP

COF, TCM

Resin-core bump packaging technology

Package Lineup

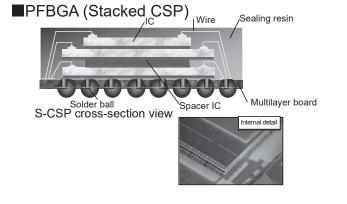
Package Externals

# 5-1 Introduction of Typical Package with High-Density Assembly

This package allows you to develop lightweight and compact products friendly to the environment by integrating the low power CMOS LSI, that is a key device, with the high density assembly, that is a key technology.

Seiko Epson has pursued the particular assembly technology by integrating miniaturization technology (cultivated by watch manufacturing) with low power technology, including CMOS LSI technology.

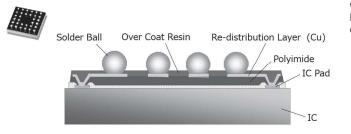
Seiko Epson intends to proceed reinforcing the global and speedy technical development power and exposing information for IT and digital network society that will continue to evolve further today. Seiko Epson will timely propose the thin, light-weight, and high-density assembly technology as the total solution, which enhances the commercial value when you en-visage the development of products.

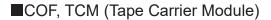


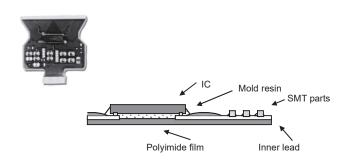
PFBGA allows you to greatly reduce the mounting area by mix and layer-stacking IC chips in one package, and to mix-load memory, microcomputer, sound source ICs and so on according to your system requirements.

Outline specifications Connection method: Wire bonding connection Package height : 1.4mm Max. (3chips Max. + Spacer) 1.2mm Max. (Max. 2chips) Ball pitch : Min. 0.5mm

# WCSP







The <u>Wafer Level Chip Size Package</u> (WCSP) is optimum as a light weight, compact and thin package of portable devices that require high-density packaging. The WCSP is available in RTC, PLL and other medium and small pin device applications.

- Space saving package with full real chip size
- Ball pitch: 0.65/0.5/0.4mm pitch
- Under-filling is not required because this package provides a stress reduction structure at secondary mounting.
- This package facilitates changing from a conventional interposer-type package; so, it enables you to replace bare-chip mounting (wire bonding or face-down bonding) with SMT mounting.

IC chips and SMT parts are mounted on a film substrate to realize not only a thin packaging but also a lightweight, compact and high-density package of high degree of freedom.

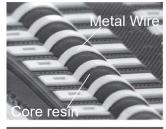
Also, gold or tin-plated lead can be bonded to gold bumps, and this inner lead bonding method has a characteristic of low impedance. This package is applicable mainly to LCD drivers and composite modules loaded with a driver and peripheral devices and customizable with them.

- Gold or tin -plated outer lead
- Package thickness : Less than 1mm
- Ease of multi-pin use

# Resin-Core Bump COG Mouting technology

The resin core bump technology allows bonding to an elastic resin as the core (having almost the same height as the conventional bump) and metal wirings on the core. This technology replaces the conventional gold bump, forms the bump on IC pins and allows direct bonding of bump wiring and the wiring on the substrate (ITO coating and others) without using ACF particles while maintaining the resin's elastic characteristics.

### Resin -core bump



Metal

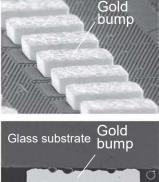
Wire

Core resin

Glass substrate

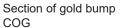
IC

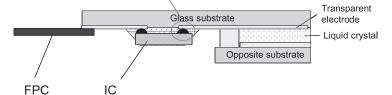
# Conventional gold bump



Section of resin-core bump







IC

Because the resin is much more elastic than ACF particles (several  $\mu m \phi),$  the traceability (or connection stability) to the variation of substrate or IC thickness and others can be significantly improved.

This technology can to a long way to solving the problems of conventional COG technology, such as the poor connection stability (point connection) due to the use of low-elastic ACF particle collection, and poor insulation between bumps.

Although the current application of this technology is COG-packaging LCD drivers and other devices, it is anticipated that it will be applicable to other packaging designs in the future.

- Significantly improves connection reliability.
- Allows fine bump pitch through photolithography technology.
- Allows highly flexible bump layout through relocation wiring technology.
- Minimizes environmental load because the soldering process is not used.

Unit: mm

Unit: mm

Unit: mm

Unit: mm

# 5-2 Package Lineup

5

# PFBGA (Plastic Fine-pitch Ball Grid Array)

Number of pins	Epson package name	JEITA package name	Body size (Nom.)	Mounting height (Max.)	Ball pitch	Storage rank
48	PFBGA7U-48	P-TFBGA-048-0707-0.80	7 X 7	1.2	0.8	MSL2a
60	PFBGA5U-60	P-TFBGA-060-0505-0.50	5 X 5	1.2	0.5	MSL2a
81	PFBGA8U-81	P-TFBGA-081-0808-0.80	8 X 8	1.2	0.8	MSL2a
96	PFBGA6U-96	P-TFBGA-096-0606-0.50	6 X 6	1.2	0.5	MSL2a
100	PFBGA7U-100	P-TFBGA-100-0707-0.65	7 X 7	1.2	0.65	MSL2a
112	PFBGA8U-112	P-TFBGA-112-0808-0.65	8 X 8	1.2	0.65	MSL2a
121	PFBGA8U-121	P-TFBGA-121-0808-0.65	8 X 8	1.2	0.65	MSL2a
121	PFBGA10U-121	P-TFBGA-121-1010-0.80	10 X 10	1.2	0.8	MSL2a
144	PFBGA7U-144	P-TFBGA-144-0707-0.50	7 X 7	1.2	0.5	MSL2a
144	PFBGA10U-144	P-TFBGA-144-1010-0.80	10 X 10	1.2	0.8	MSL2a
160	PFBGA10U-160	P-TFBGA-160-1010-0.65	10 X 10	1.2	0.65	MSL2a
161	PFBGA8U-161	P-TFBGA-161-0808-0.50	8 X 8	1.2	0.5	MSL2a
177	PFBGA13U-177	P-TFBGA-177-1313-0.80	13 X 13	1.2	0.8	MSL2a
180	PFBGA10U-180	P-TFBGA-180-1010-0.65	10 X 10	1.2	0.65	MSL2a
180	PFBGA12U-180	P-TFBGA-180-1212-0.80	12 X 12	1.2	0.8	MSL2a
181	PFBGA8U-181	P-TFBGA-181-0808-0.50	8 X 8	1.2	0.50	MSL2a
208	PFBGA12U-208	P-TFBGA-208-1212-0.65	12 X 12	1.2	0.65	MSL2a
220	PFBGA14U-220	P-TFBGA-220-1414-0.80	14 X 14	1.2	0.8	MSL2a
256	PFBGA14U-256	P-TFBGA-256-1414-0.80	14 X 14	1.2	0.8	MSL2a
280	PFBGA16U-280	P-TFBGA-280-1616-0.80	16 X 16	1.2	0.8	MSL2a

# ■VFBGA (Very Thin Fine-pitch Ball Grid Array)

VFBG	A (Very Thin Fine-p	itch Ball Grid Array)				Unit: mm
Number of pins	Epson package name	JEITA package name	Body size (Nom.)	Mounting height (Max.)	Ball pitch	Storage rank
49	VFBGA4H-49	P-VFBGA-049-0404-0.50	4 X 4	1.0	0.5	MSL2a
81	VFBGA5H-81	P-VFBGA-081-0505-0.50	5 X 5	1.0	0.5	MSL2a
81	VFBGA8H-81	P-VFBGA-081-0808-0.80	8 X 8	1.0	0.8	MSL2a
96	VFBGA6H-96	P-VFBGA-096-0606-0.50	6 X 6	1.0	0.5	MSL2a
121	VFBGA6H-121	P-VFBGA-121-0606-0.50	6 X 6	1.0	0.5	MSL2a
121	VFBGA10H-121	P-VFBGA-121-1010-0.80	10 X 10	1.0	0.8	MSL2a
144	VFBGA7H-144	P-VFBGA-144-0707-0.50	7 X 7	1.0	0.5	MSL2a
144	VFBGA10H-144	P-VFBGA-144-1010-0.80	10 X 10	1.0	0.8	MSL2a
161	VFBGA7H-161	P-VFBGA-161-0707-0.50	7 X 7	1.0	0.5	MSL2a
180	VFBGA10H-180	P-VFBGA-180-1010-0.65	10 X 10	1.0	0.65	MSL2a
181	VFBGA8H-181	P-VFBGA-181-0808-0.50	8 X 8	1.0	0.5	MSL2a
240	VFBGA10H-240	P-VFBGA-240-1010-0.50	10 X 10	1.0	0.5	MSL2a

# PBGA (Plastic Ball Grid Array)

Number of pins	Epson package name	JEITA package name	Body size (Nom.)	Mounting height (Max.)	Ball pitch	Storage rank
256	PBGA1UC256	P-LBGA-0256-1717-1.00	17 X 17	1.3	1.0	MSL3
256	PBGA1UE256	P-LBGA-0256-1717-1.00	17 X 17	1.7	1.0	MSL3

# LQFP (Low profile Quad Flat Package)

Number of pins	Epson package name	JEITA package name	Body size (Nom.)	Mounting height (Max.)	Lead pitch	Lead shape	Storage rank
48	QFP12-48PIN	P-LQFP048-0707-0.50	7 X 7	1.7	0.5	STD	MSL2a
64	QFP13-64PIN	P-LQFP064-1010-0.50	10 X 10	1.7	0.5	STD	MSL3
80	QFP14-80PIN	P-LQFP080-1212-0.50	12 X 12	1.7	0.5	STD	MSL3
100	QFP15-100PIN	P-LQFP100-1414-0.50	14 X 14	1.7	0.5	STD	MSL3
128	QFP15-128PIN	P-LQFP128-1414-0.40	14 X 14	1.7	0.4	STD	MSL3
144	QFP20-144PIN	P-LQFP144-2020-0.50	20 X 20	1.7	0.5	STD	MSL3 *
176	QFP21-176PIN	P-LQFP176-2424-0.50	24 X 24	1.7	0.5	STD	MSL3 *
208	QFP22-208PIN	P-LQFP208-2828-0.50	28 X 28	1.7	0.5	STD	MSL3 *
216	QFP21-216PIN	P-LQFP216-2424-0.40	24 X 24	1.7	0.4	STD	MSL3 *
256	QFP22-256PIN	P-LQFP256-2828-0.40	28 X 28	1.7	0.4	STD	MSL3 *

\* Some products must be stored under different conditions. Contact Epson for details.

# ■TQFP (Tin Quad Flat Package)

		<u> </u>					
Number of pins	Epson package name	JEITA package name	Body size (Nom.)	Mounting height (Max.)	Lead pitch	Lead shape	Storage rank
48	TQFP12-48PIN	P-TQFP048-0707-0.50	7 X 7	1.2	0.5	STD	MSL2a
64	TQFP12-64PIN	P-TQFP064-0707-0.40	7 X 7	1.2	0.4	STD	MSL2a
64	TQFP13-64PIN	P-TQFP064-1010-0.50	10 X 10	1.2	0.5	STD	MSL2a *
80	TQFP14-80PIN	P-TQFP080-1212-0.50	12 X 12	1.2	0.5	STD	MSL3
100	TQFP14-100PIN	P-TQFP100-1212-0.40	12 X 12	1.2	0.4	STD	MSL3
100	TQFP15-100PIN	P-TQFP100-1414-0.50	14 X 14	1.2	0.5	STD	MSL3 *
128	TQFP15-128PIN	P-TQFP128-1414-0.40	14 X 14	1.2	0.4	STD	MSL3 *

\* Some products must be stored under different conditions. Contact Epson for details.

# ■QFN (Quad Flat Non-leaded Package)

Number of pins	Epson package name	JEITA package name	Body size (Nom.)	Mounting height (Max.)	Lead pitch	Lead shape	Storage rank
16	SQFN4-16PIN	P-VQFN016-0404-0.65	4 X 4	1.0	0.65	STD	MSL2a
24	SQFN4-24PIN	P-VQFN024-0404-0.50	4 X 4	1.0	0.5	STD	MSL2a
32	SQFN4-32PIN	P-VQFN032-0404-0.40	4 X 4	1.0	0.4	STD	MSL2a
32	SQFN5-32PIN	P-VQFN032-0505-0.50	5 X 5	1.0	0.5	STD	MSL2a
36	SQFN6-36PIN	P-VQFN036-0606-0.50	6 X 6	1.0	0.5	STD	MSL2a
48	SQFN7-48PIN	P-VQFN048-0707-0.50	7 X 7	1.0	0.5	STD	MSL2a
64	SQFN9-64PIN	P-VQFN064-0909-0.50	9 X 9	1.0	0.5	STD	MSL2a
76	SQFN9-76PIN	P-VQFN076-0909-0.40	9 X 9	1.0	0.4	STD	MSL2a
80	SQFN9-80PIN	P-VQFN080-0909-0.40	9 X 9	1.0	0.4	STD	MSL2a

# SON (Small Outline Non-leaded Package)

Number of pins	Epson package name	JEITA package name	Body size (Nom.)	Mounting height (Max.)	Lead pitch	Lead shape	Storage rank
6	SON-6PIN	P-WSON06-02.60x01.60-0.50	1.6 X 2.6	0.8	0.5	STD	MSL2a
8	SON1-8PIN	P-VSON08-03.08x03.00-0.65	3 X 3.8	1.0	0.65	STD	MSL2a
16	SON2-16PIN	P-VSON16-04.40x05.30-0.65	5.3 X 4.4	1.0	0.65	STD	MSL2a
6	VSON-6PIN	P-USON06-01.20x01.60-0.50	1.6 X 1.2	0.6	0.5	STD	MSL2

# SOP (Small Outline Package)

Number of pins	Epson package name	JEITA package name	Body size (Nom.)	Mounting height (Max.)	Lead pitch	Lead shape	Storage rank
8	SOP3B-8PIN	P-SOP08-03.90x04.90-1.27	4.9 X 3.9	1.75	1.27	STD	MSL2a
8	SOP3C-8PIN	P-LSOP08-04.40x05.00-1.27	5.0 X 4.4	1.7	1.27	STD	MSL2
16	SOP3A-16PIN	P-LSOP16-04.40x10.00-1.27	10.0 X 4.4	1.7	1.27	STD	MSL2a

# SSOP (Shrink Small Outline Package)

Number of pins	Epson package name	JEITA package name	Body size (Nom.)	Mounting height (Max.)	Lead pitch	Lead shape	Storage rank
16	SSOP2-16PIN	P-LSSOP16-04.40x06.60-0.80	6.6 X 4.4	1.7	0.8	STD	MSL4

# SOT (Small Outline Transistor Package)

Number of pins	Epson package name	Package name	Body size (Nom.)	Mounting height (Max.)	Lead pitch	Lead shape	Storage rank
3	SOT89-3PIN	(P-SOT89-3)	4.5 X 2.5	1.6	1.5	STD	MSL2a

# ■PLP (Plating Lead Package)

Number of pins	Epson package name	Package name	Body size (Nom.)	Mounting height (Max.)	Lead pitch	Lead shape	Storage rank
8	PLP061616B-8PIN	(P-UPLP008-01.60x01.60-0.50)	1.6 X 1.6	0.65	0.5	STD	MSL2a
10	PLP062725A-10PIN	(P-UPLP010-02.50x02.70-0.50)	2.7 X 2.5	0.65	0.5	STD	MSL2a
10	PLP063031A-10PIN	(P-UPLP010-03.10x03.00-0.50)	3.0 X 3.1	0.65	0.5	STD	MSL2a
28	PLP064040A-28PIN	(P-UPLP028-04.00x04.00-0.50)	4.0 X 4.0	0.65	0.5	STD	MSL2a

## Package diagrams, storage rank documents, and various environment-related information Available on the following Web page.

global.epson.com/products\_and\_drivers/semicon/

Information > Technology Information/Package > Package Lineup

35

Unit: mm

Unit: mm

Unit: mm

Unit: mm

5

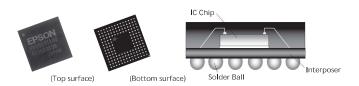
Unit: mm

Unit: mm

# 5-3 Package Externals

VFBGA (Very Thin Fine-pitch Ball Grid Array) & PFBGA (Plastic Fine-pitch Ball Grid Array)

5

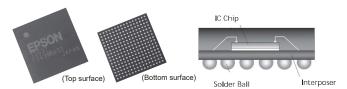


ΡΚG Τγ	be	Body Size (mm)	Ball Pitch (mm)
VFBGA4H-49		4 x 4 x 1.0	0.5
PFBGA5U-60		5 x 5 x 1.2	0.5
VFBGA5H-81		5 x 5 x 1.0	0.5
VFBGA6H-96 PFBGA6U-96		6 x 6 x 1.0 6 x 6 x 1.2	0.5
VFBGA6H-121		6 x 6 x 1.0	0.5
VFBGA7H-144 PFBGA7U-144		7 x 7 x 1.0 7 x 7 x 1.2	0.5
VFBGA7H-161		7 x 7 x 1.0	0.5
PFBGA8U-161		8 x 8 x 1.2	0.5
VFBGA8H-181 PFBGA8U-181		8 x 8 x 1.0 8 x 8 x 1.2	0.5
VFBGA10H-240		10 x 10 x 1.0	0.5
PFBGA7U-100		7 x 7 x 1.2	0.65
PFBGA8U-112		8 x 8 x 1.2	0.65
PFBGA8U-121		8 x 8 x 1.2	0.65

PKG T	уре	Body Size (mm)	Ball Pitch (mm)	
PFBGA10U-160		10 x 10 x 1.2	0.65	
PFBGA10U-180		10 x 10 x 1.2	0.65	
PFBGA12U-208		12 x 12 x 1.2	0.65	
PFBGA7U-48		7 x 7 x 1.2	0.8	
VFBGA8H-81 PFBGA8U-81		8 x 8 x 1.0 8 x 8 x 1.2	0.8	
VFBGA10H-121 PFBGA10U-121	$\begin{smallmatrix} 0 & 0 & 0 & 0 & 0 & 0 & 0 & 0 & 0 \\ 0 & 0 &$	10 x 10 x 1.0 10 x 10 x 1.2	0.8	
VFBGA10H-144 PFBGA10U-144	$\left \begin{array}{cccccccccccccccccccccccccccccccccccc$	10 x 10 x 1.0 10 x 10 x 1.2	0.8	
PFBGA12U-180	$\begin{smallmatrix} 0 & 0 & 0 & 0 & 0 & 0 & 0 & 0 & 0 & 0 $	12 x 12 x 1.2	0.8	
PFBGA14U-220		14 x 14 x 1.2	0.8	
PFBGA16U-280		16 x 16 x 1.2	0.8	

## **Package Information**

## PBGA (Plastic Ball Grid Array)



PKG 1	ӯре	Body Size (mm)	Ball Pitch (mm)
PBGA1UC256 PBGA1UE256		17 x 17 x 1.3 17 x 17 x 1.7	1.0

## SQFN (Saw Quad Flat Non-leaded Package)



РКС Туре		Body Size (mm)	Lead Pitch (mm)
SQFN4-24PIN		4 x 4 x 1.0	0.5
SQFN5-32PIN		5 x 5 x 1.0	0.5
SQFN6-36PIN		6 x 6 x 1.0	0.5
SQFN7-48PIN		7 x 7 x 1.0	0.5
SQFN9-64PIN		9 x 9 x 1.0	0.5

## LQFP (Low profile Quad Flat Package) & TQFP (Thin

## Quad Flat Package)

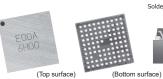
РКС Туре		Body Size (mm)	Lead Pitch (mm)
QFP12-48PIN		7 x 7 x 1.7	0.5
QFP13-64PIN		10 x 10 x 1.7	0.5
QFP14-80PIN		12 x 12 x 1.7	0.5
QFP15-100PIN		14 x 14 x 1.7	0.5
QFP15-128PIN		14 x 14 x 1.7	0.4
QFP20-144PIN		20 x 20 x 1.7	0.5
QFP21-176PIN		24 x 24 x 1.7	0.5
QFP22-208PIN		28 x 28 x 1.7	0.5

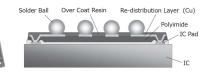
PKG Type		Body Size (mm)	Lead Pitch (mm)
QFP22-256PIN		28 x 28 x 1.7	0.4

5

Lead Body Size PKG Type Pitch (mm) (mm) TQFP12-48PIN 7 x 7 x 1.2 0.5 TQFP12-64PIN 7 x 7 x 1.2 0.4 TQFP13-64PIN 10 x 10 x 1.2 0.5 TQFP14-80PIN 12 x 12 x 1.2 0.5 TQFP14-100PIN 12 x 12 x 1.2 0.4 TQFP15-100PIN 14 x 14 x 1.2 0.5 ...... TQFP15-128PIN 14 x 14 x 1.2 0.4 

## WCSP (Wafer level Chip Scale Package)





Products	8	Ball Count	Body Size (mm)	Ball Pitch (mm)
WCSP-36		36	2.5 x 2.5 x 0.34	0.35
WCSP-41		41	3.4 x 2.6 x 0.7	0.4
WCSP-48		48	3.9 x 3.9 x 0.9	0.5
WCSP-49		49	3.0 x 3.0 x 0.8	0.4
WCSP-49		49	4.2 x 4.2 x 0.8	0.5
WCSP-96		96	4.5 x 4.5 x 0.7	0.4

## **LSI Device Precautions**

## 1. General precautions for use of CMOS LSI devices

Seiko Epson's CMOS LSI devices are designed and manufactured to assure trouble-free operation when used under normal operating conditions. All products are subjected to stringent electrical and mechanical testing to ensure reliability, but users are strongly recommended to observe the following precautions when designing systems, handling or storing devices to minimize the chance of failure.

#### Cautions to be observed when designing

#### Use within the rated ranges

Use ICs not to exceed the rated ranges of operating voltage, temperature, input/output voltage and current. Devices may sometimes work properly for a short period of time even when used outside the rated ranges, but their failure ratio may increase. Even within the rated conditions, failure ratio will change depending on the operating temperature and voltage of embedded systems. This must be fully considered when designing systems.

#### Handling of input/output control pins

When a noise such as spark and electrostatic is given from an input or output terminals, IC may malfunction. Pay sufficient attention in product designing. Electromagnetic interference can cause ICs to operate erratically. Shield all interference sources in equipment that uses ICs.

#### Latch up phenomenon

Excessive electrical noise occurred to a power or input/output pin can cause ICs to latch up, resulting in device malfunction or damage. If this occurs, turn off the power, isolate the problem, then supply power again.

#### Protection against electrostatic discharge (ESD)

Although all pins are equipped with an anti-electro static circuit, electro static beyond the capacity may lead to breakage. Take appropriate countermeasures when handling ICs.

- Avoid using packing and transporting containers made of plastic. Use electrically conductive containers. Also, special care must be taken when handling ICs, by wearing a antistatic wrist strap or taking other possible measures.
- Use a soldering iron and test circuits without high voltage leakage with grounding.

#### Notes on storage

#### Storage condition

- Take care so that packages are not subjected to impact, vibration or water leakage.
- Do not store and use the product under conditions where moisture condensation may be formed due to rapid changes in temperature. Also, do not put load on products.
- When storing, avoid dusty locations or locations with corrosive gases.
- After a long period of storage, check to see that the pins are not discolored, solderability is not degraded, etc., before use.
- Check moisture-proof bags for tear or wear before use. Also check the silica gel in the bag has not absorbed moisture when the bag is opened.
- Storage conditions after opening a moisture proof-bag, soldering method and soldering temperature must meet the requirements specified by Epson for respective products.

#### Conditions of use environment

#### Precautions for use environment

Use the IC in the proper temperature and humidity. The humidity must be 85% or lower (to prevent dew condensation). In the environment where the IC is directly exposed to dust, salt, or acid gas such as SO2, it may cause electrical leakage between leads or corrosion. In order to prevent such problems, apply corrosion-proof coatings to printed circuit boards and ICs.

#### Protection against excessive physical stresses and rapid temperature change

Do not expose ICs to excessive mechanical vibration, repetitive shock stress, or rapid temperature changes. These can cause the plastic package resin to crack and/or the bonding wires to break.

#### Light shading precaution

Exposing semiconductor devices to the light may have a chance to lead to miss function, since the light affects the device characteristics.

To prevent IC from miss function, please take into account the following points about substrates and products, packaged with IC.

- At product design and assembly, please consider the product structure so that IC is shaded in actual use.
- At testing process, please provide shaded environment for the device under test.
- ·Please consider surface, back and side of IC chip, since IC should be shaded entirely.

## 2. Package products

## 2.1 Cautions on surface mount

#### **Mechanical stress**

Minimize mechanical stress to a printed circuit board during or after soldering. The load applied from the surface when soldering a package onto the printed circuit board must be within 10N (1Kgf).

#### Package leads

As for a surface mount device, the pattern on a board and the lead of a package are soldered surface to surface. Although we are shipping products securing sufficient lead flatness for soldering, when handling, take care not to apply force otherwise it may result in deformation of the lead.

#### Signal leads on the package surface

Some packages are structured to expose a portion of the signal leads on the surface. When using these products, pay sufficient attention not to let the package be soiled. Also, handling with bare hands must be avoided.

## Soldering precautions

Use infrared or air reflow or the combination of these methods for soldering. Nitrogen reflow is recommended to inhibit the effects of oxidation and improve wettability.

#### Thermal stress to packages

Soldering process is recommended to be carried out in the shortest time at the lowest temperature to minimize thermal stress to packages. Settings of the soldering profile should be performed upon through confirmation that the state of soldering and reliability after soldering are optimized.

#### Solder reflow processing multiple times

If solder reflow is to be carried out multiple times, it should be performed within the allowable storage period specified as storage rank for each product. (Reflow is allowed twice.)

#### i. Hand soldering

Hand soldering using a soldering iron should be performed under the following conditions:

Maximum temperature of the soldering iron	Time	Times
350 °C	Within 5 sec per pin	Twice or less

Pay sufficient attention not to let a soldering iron contact any parts other than leads, such as a package body.

#### ii. Flow soldering

Flow soldering is not recommended.

## **LSI Device Precautions**

## 2.2 Notes on storage

#### Moisture absorption and reliability

The resin used in surface-mount packages absorbs moisture over time even stored in room conditions. When IC packages are put into reflow ovens with much moisture absorption, the resin may have a crack or a delamination between the resin and lead frame may occur. Therefore, surface mount ICs must be kept under typical storage conditions shown below before reflow soldering.

#### ■ Typical storage conditions and storage periods for (Surface-Mount) IC packages

Storage condition	Storage environments before opening the bag	
Before opening sealed	30°C, 85% RH or less	Within 12 months (1 year)
moisture proof bag		

#### • Storage ranks and storage conditions

Storage rank	Storage environments after opening the bag	
MSL2	30°C, 70% RH or less	Within 12 months (1 year)
MSL2a	30°C, 70% RH or less	Within a month
MSL3	30°C, 70% RH or less	Within 168 hours(1 Week)
MSL4	30°C, 70% RH or less	Within 72 hours(3 days)

•Regarding the storage ranks of respective products (IC packages) after opening the moisture-proof bags, refer to the tables of storage ranks shown in 5-2 Package Lineup.

#### Surface-mount package baking conditions

When surface-mount IC packages exceed the recommended storage periods, or their storage periods or storage conditions are unknown and therefore moisture absorption is a concern, it is recommended to dry-bake them before reflow soldering. This baking process will prevent the resin from cracking during soldering. When dry-baking, see below.

•Standard baking conditions for IC packages

Baking temperature	Baking hours	Max. Baking times
125±5°C	From 20 to 36 hours	Twice

•When the storage duration after opening the bag exceeds the specified period or unknown, re-bake packages before mounting.

•Storage conditions from the baking to the reflow soldering are the same as the above-mentioned storage conditions.

Note: If products are shipped in Tape & Reel, transfer the products into heatproof trays before baking.

## 3. Bare chips

#### General precautions

- •The passivation film applied on bare chip surface is not to protect the chip from external shock but to protect the internal metallization.
- Moisture and dust in the air and careless handling of products during assembly will lead to defective products. Adequate caution must be exercised for storage environment and chip handling.

### Packing

•When bare chips are shipped, they are put in dedicated trays, and the trays are clipped so that chips are properly held in the trays during transportation. Then the trays are packed in antistatic bags. Do not open the bags more than necessary to prevent foreign substances from coming into the bags and falling on the chips inside. Do not leave trays open, either.

#### Bare chip storage precautions

- •Allowable storage periods before and after opening the pack are maximum 12 months under the conditions mentioned below.
- •If the bags are opened, assemble the products without much delay in order to prevent the bonding degradation caused by the quality change in the bonding pad surfaces.

#### Bare chip storage conditions and storage periods

State	Storage conditions	Allowable storage period
Before opening	Lower than 35°C, 80% RH point	6 months
After opening	Lower than 30°C, 80% RH point	30 days
	In dry N2 gas with dew point lower than -30°C	6 months

#### Bare chip mounting

#### Mounting environment

- Perform bare chip mounting in the clean environment where chip surface is not exposed to contaminated air or substances.
- Die pick up method
- It is recommended to use a die collet for picking up a die. Choose die collets that can minimize the contact area on the chip.
- Mount boards (PCBs, etc.)

Use boards where no residues such as chemicals are left, or conductive failure (such as bonding failure) or Al pad corrosion may occur.

Pick up tool control

Clean the pick up tool periodically. Any foreign substance attached to the collet will lead high rate of continuous failures.

Bare chip cleaning

Do not clean bare chips. If bare chips are cleaned, extreme caution must be exercised about residues on chips.

• Protection from static electricity Use products in the environment where they are not exposed to ESD. When mounting a bare chip, mount it after assembling all other peripheral parts.

#### Material

• For mold resins, use "semiconductor grade" products. This is recommended to prevent corrosion in bonding pads due to moisture absorption, or the mold resign internal stress due to temperature changes. Similar precautions must be taken for other materials to be used.

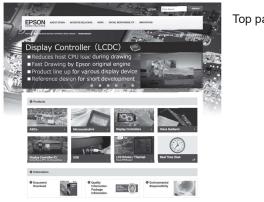
## Non-Promotional Product Information

Epson is considering the discontinuation of the following products, though they will be continuously supplied to the customers currently using them. For your new projects, however, please consider alternative products. For the latest non-promotional product information, please visit the Epson website.

Products	Model name
16-bit Microcontrollers	S1C17965
Display controllers	S1D13746F01A、S1D13746B01B

## Information on CMOS LSI's

Epson provides a number of sources of information regarding its products, including catalogs, brochures, technical manuals, and software on the website. global.epson.com/products\_and\_drivers/semicon



Top page





Manuals

Data Sheets



Brochures

## Explanation of the mark that are using it for the catalog



Designed for automotive applications such as Car Multimedia, Body Electronics, Remote Keyless Entry etc.

#### NOTICE : PLEASE READ CAREFULLY BELOW BEFOR USE THIS DOCUMENT

The content of this document is subject to change without notice.

- 1. This document may not be copied, reproduced, or used for any other purposes, in whole or in part, without the consent of Seiko Epson Corporation("Epson").
- 2. Before purchasing or using Epson products, please contact with our sales representative for the latest information and be always sure to check the latest information published on Epson's official web sites and sources.
- 3. Information provided in this document such as application circuits, programs, usage, etc., are for reference purpose only. Epson makes no guarantees against any infringements or damages to any third parties' intellectual property rights or any other rights resulting from the information. This document does not grant you any licenses, intellectual property rights or any other rights with respect to Epson products owned by Epson or any third parties.
- 4. Epson is committed to constantly improving quality and reliability, but semiconductor products in general are subject to malfunction and failure. In using Epson products, you shall be responsible for safe design in your products; your hardware, software and systems are designed enough to prevent any harm or damages to life, health or property even if any malfunction or failure might be caused by Epson products. In designing of your products with using Epson products, please be sure to check and comply with the latest information regarding Epson products (this document, specifications, data sheets, manuals, Epson's web site, etc.). When using the information included in the above materials such as product data, chart, technical contents, programs, algorithms and application circuit examples, you shall evaluate your products both in stand-alone basis and within your overall systems. You shall be solely responsible for deciding whether or not to adopt and use Epson products.
- 5. Epson has prepared this document carefully to be accurate and dependable, but Epson does not guarantee that the information is always accurate and complete. Epson assumes no responsibility for any damages which you incurred by due to misinformation in this document.
- No dismantling, analysis, reverse engineering, modification, alteration, adaptation, reproduction, etc., of Epson products is allowed.
   Epson products have been designed, developed and manufactured to be used in general electronic applications (office equipment, communications equipment, measuring instruments, home electronics, etc.) and applications individually listed in this document
- communications equipment, measuring instruments, home electronics, etc.) and applications individually listed in this document ("General Purpose"). Epson products are NOT intended for any use beyond the General Purpose that requires particular/higher quality or reliability in order to refrain from causing any malfunction or failure leading to harm to life, health or serious property damage or severe impact on society, including, but not limited to listed below. Therefore, you are advised to use Epson products only for the General Purpose. Should you desire to buy and use Epson products for the particular purpose other than the General Purpose, Epson makes no warranty and disclaims with respect to Epson products, whether express or implied, including without limitation any implied warranty of merchantability or fitness for any particular purpose. Please be sure to contact our sales representative and obtain an approval in advance.

[Particular purpose]

Space equipment (artificial satellites, rockets, etc.)/

Transportation vehicles and their control equipment (automobiles, aircraft, trains, ships, etc.)/

Medical equipment (other than applications individually listed in this document)/

Relay equipment to be placed on sea floor/ Power station control equipment/ Disaster or crime prevention equipment/ Traffic control equipment/ Financial equipment/

- Other applications requiring similar levels of reliability as the above
- 8. Epson products listed in this document and our associated technologies shall not be used in any equipment or systems that laws and regulations in Japan or any other countries prohibit to manufacture, use or sell. Furthermore, Epson products and our associated technologies shall not be used for developing military weapons of mass destruction, military purpose use, or any other military applications. If exporting Epson products or our associated technologies, you shall comply with the Foreign Exchange and Foreign Trade Control Act in Japan, Export Administration Regulations in the U.S.A (EAR) and other export-related laws and regulations in Japan and any other countries and follow the required procedures as provided by the relevant laws and regulations.
- 9. Epson assumes no responsibility for any damages (whether direct or indirect) caused by or in relation with your non-compliance with the terms and conditions in this document.
- 10. Epson assumes no responsibility for any damages (whether direct or indirect) incurred by any third party that you assign, transfer, loan, etc., Epson products.
- 11. For more details or other concerns about this document, please contact our sales representative.
- 12. Company names and product names listed in this document are trademarks or registered trademarks of their respective companies.

## ©Seiko Epson Corporation 2021

#### [Registered trademarks, trademarks, and company names]

Design Compiler<sup>®</sup> : Synopsys Inc. in U.S.A.

NC-Verilog<sup>®</sup> : Cadence Design Systems Inc. in U.S.A.

Compact Flash® : Western Digital Corporation or its affiliates in the US and/or other countries

SuperFlash<sup>®</sup> : Silicon Storage Technology, Inc., in the U.S.A.

Arm and Cortex are registered trademarks of Arm Limited (or its subsidiaries) in the US and/or elsewhere.

Other brand names and product names are trademarks or registered trademarks of their respective owners.

MMP Technology

Supply of this implementation of TPL's MMP technology does not convey a license nor imply a right under any patent, or any other industrial or intellectual property right of TPL, to use this implementation in any finished end-user final product. You are hereby notified that a license for such use is required from TPL. Contact: "<u>mmp-licensing@tplgroup.net</u>"

# **EPSON**

## **International Sales Operations**

#### America

Epson America, Inc.

Headquarter: 3131 Katella Ave., Los Alamitos, CA 90720, USA Phone: +1-562-290-4677

San Jose Office: 214 Devcon Drive San Jose, CA 95112 USA Phone: +1-800-228-3964 or +1-408-922-0200

#### Europe

 Epson Europe Electronics GmbH

 Riesstrasse 15, 80992 Munich,

 Germany

 Phone: +49-89-14005-0

 FAX: +49-89-14005-110

## Asia

Epson (China) Co., Ltd.4th Floor, Tower 1 of China Central Place, 81 Jianguo Road, ChaoyangDistrict, Beijing 100025 ChinaPhone: +86-10-8522-1199FAX: +86-10-8522-1120

#### Shanghai Branch

Room 1701 & 1704, 17 Floor, Greenland Center II, 562 Dong An Road, Xu Hui District, Shanghai, China Phone: +86-21-5330-4888 FAX: +86-21-5423-4677

#### Shenzhen Branch

Room 804-805, 8 Floor, Tower 2, Ali Center,No.3331 Keyuan South RD(Shenzhen bay), Nanshan District, Shenzhen 518054, China Phone: +86-10-3299-0588 FAX: +86-10-3299-0560

#### Epson Taiwan Technology & Trading Ltd.

15F., No.100, Songren Rd., Sinyi Dist., Taipei City 110. Taiwan Phone: +886-2-8786-6688

#### Epson Singapore Pte., Ltd.

438B Alexandra Road, Block B Alexandra TechnoPark, #04-01/04, Singapore 119968 Phone: +65-6586-5500 FAX: +65-6271-7066

#### Epson Korea Co., Ltd.

10F Posco Tower Yeoksam, Teheranro 134 Gangnam-gu. Seoul, 06235, Korea Phone: +82-2-3420-6695

Seiko Epson Corp. Sales & Marketing Division

#### **Device Sales & Marketing Department**

29th Floor, JR Shinjyuku Miraina Tower, 4-1-6 Shinjyuku, Shinjyuku-ku, Tokyo 160-8801, Japan









## SEIKO EPSON CORPORATION

global.epson.com/products\_and\_drivers/semicon/

Document code : 701079445 First Issue April 2002 Revised March 2021 in JAPAN (H)